

Products Catalog

Fixed Resistors

- General purpose chip resistors type
- High precision type
- Current sensing type
- Small & High power type

- Anti-Sulfurated type
- High temperature type
- Resistor network / Array type



IN Your Future





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Guidelines and precautions regarding the technical information and use of our products described in this online catalog.

- If you want to use our products described in this online catalog for applications requiring special qualities or reliability, or for applications where the failure or malfunction of the products may directly jeopardize human life or potentially cause personal injury (e.g. aircraft and aerospace equipment, traffic and transportation equipment, combustion equipment, medical equipment, accident prevention, anti-crime equipment, and/or safety equipment), it is necessary to verify whether the specifications of our products fit to such applications. Please ensure that you will ask and check with our inquiry desk as to whether the specifications of our products fit to such applications use before you use our products.
- The quality and performance of our products as described in this online catalog only apply to our products when used in isolation. Therefore, please ensure you evaluate and verify our products under the specific circumstances in which our products are assembled in your own products and in which our products will actually be used.
- If you use our products in equipment that requires a high degree of reliability, regardless of the application, it is recommended that you set up protection circuits and redundancy circuits in order to ensure safety of your equipment.
- The products and product specifications described in this online catalog are subject to change for improvement without prior notice. Therefore, please be sure to request and confirm the latest product specifications which explain the specifications of our products in detail, before you finalize the design of your applications, purchase, or use our products.
- The technical information in this online catalog provides examples of our products' typical operations and application circuits. We do not guarantee the non-infringement of third party's intellectual property rights and we do not grant any license, right, or interest in our intellectual property.
- If any of our products, product specifications and/or technical information in this online catalog is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially with regard to security and export control, shall be observed.

<Regarding the Certificate of Compliance with the EU RoHS Directive/REACH Regulations>

- The switchover date for compliance with the RoHS Directive/REACH Regulations varies depending on the part number or series of our products.
- When you use the inventory of our products for which it is unclear whether those products are compliant with the RoHS Directive/REACH Regulation, please select "Sales Inquiry" in the website inquiry form and contact us.

We do not take any responsibility for the use of our products outside the scope of the specifications, descriptions, guidelines and precautions described in this online catalog.





Application Guidelines (Fixed Resistors)

Safety precautions

- When using our products, no matter what sort of equipment they might be used for, be sure to make a written agreement on the specifications with us in advance. The design and specifications in this catalog are subject to change without prior notice.
- Do not use the products beyond the specifications described in this catalog.
- This catalog explains the quality and performance of the products as individual components. Before use, check and evaluate their operations when installed in your products under the actual conditions for use.
- Install the following systems for a failsafe design to ensure safety if these products are to be used in equipment
 where a defect in these products may cause the loss of human life or other significant damage, such as
 damage to vehicles (automobile, train, vessel), traffic lights, medical equipment, aerospace equipment,
 electric heating appliances, combustion/gas equipment, rotating equipment, and disaster/crime prevention
 equipment.
 - * Systems equipped with a protection circuit and a protection device.
 - * Systems equipped with a redundant circuit or other system to prevent an unsafe status in the event of a single fault.
 - * Systems equipped with an arresting the spread of fire or preventing glitch.

Precautions for use

- These products are designed and manufactured for general and standard use in general elec tron ic equipment. (e.g. AV equipment, home electric appliances, office equipment, information and communication equipment) For applications in which special quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or cause threat of personal injury (such as for aircraft and aerospace equipment, traffic and transport equipment, combustion equipment, medical equipment, accident prevention and anti-theft devices, and safety equipment), please be sure to consult with our sales representative in advance and to exchange product specifications which conform to such applications.
- These products are not intended for use in the following special conditions. Before using the products, carefully check the effects on their quality and performance, and determine whether or not they can be used.
 - 1. In liquid, such as water, oil, chemicals, or organic solvent.
 - 2. In direct sunlight, outdoors, or in dust.
 - 3. In salty air or air with a high concentration of corrosive gas, such as Cl2, H2S, NH3, SO2, or NOX.
 - 4. Electric Static Discharge (ESD) Environment. These components are sensitive to static electricity and can be damaged under static shock (ESD). Please take measures to avoid any of these environments. Smaller components are more sensitive to ESD environment.
 - 5. Electromagnetic and Radioactive Environment.

 Avoid any environment where strong electromagnetic waves and radiation exist.
 - 6. In an environment where these products cause dew condensation.
 - 7. Sealing or coating of these products or a printed circuit board on which these products are mounted, with resin or other materials.
- These products generate Joule heat when energized. Carefully position these products so that their heat will not affect the other components.
- Carefully position these products so that their temperatures will not exceed the category temperature range due to the effects of neighboring heat-generating components. Do not mount or place heat-generating components or inflammables, such as vinyl-coated wires, near these products.
- Note that non-cleaning solder, halogen-based highly active flux, or water-soluble flux may deteriorate the performance or reliability of the products.
- Carefully select a flux cleaning agent for use after soldering. An unsuitable agent may deteriorate the
 performance or reliability. In particular, when using water or a water-soluble cleaning agent, be careful not to
 leave water residues. Otherwise, the insulation performance may be deteriorated.
- Do not apply flux to these products after soldering. The activity of flux may be a cause of failures in these products.
- Refer to the recommended soldering conditions and set the soldering condition. High peak temperature or long heating time may impair the performance or the reliability of these products.
- Recommended soldering condition is for the guideline for ensuring the basic characteristics of the products, not for the stable soldering conditions. Conditions for proper soldering should be set up according to individual conditions.
- Do not reuse any products after removal from mounting boards.
- Do not drop these products. If these products are dropped, do not use them. Such products may have received mechanical or electrical damage.
- If any doubt or concern to the safety on these products arise, make sure to inform us immediately and conduct technical examinations at your side.



Precautions for storage

The performance of these products, including the solderability, is guaranteed for a year from the date of arrival at your company, provided that they remain packed as they were when delivered and stored at a temperature of 5 °C to 35 °C and a relative humidity of 45 % to 85 %.

Even within the above guarantee periods, do not store these products in the following conditions. Otherwise, their electrical performance and/or solderability may be deteriorated, and the packaging materials (e.g. taping materials) may be deformed or deteriorated, resulting in mounting failures.

- 1. In salty air or in air with a high concentration of corrosive gas, such as Cl2, H2S, NH3, SO2, or NOX.
- 2. In direct sunlight.

<Package markings>

Package markings include the product number, quantity, and country of origin. In principle, the country of origin should be indicated in English.

AEC-Q200 Compliant

The products are tested based on all or part of the test conditions and methods defined in AEC-Q200. Please consult with Panasonic for the details of the product specification and specific evaluation test results, etc., and please review and approve Panasonic's product specification before ordering.



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Application Guidelines (Surface Mount Resistors)

The following are precautions for individual products. Please also refer to the common precautions for Fixed Resistors in this catalog.

- Take measures against mechanical stress during and after mounting of Surface Mount Resistors
 (hereafter called the resistors) so as not to damage their electrodes and protective coatings.
 Be careful not to misplace the resistors on the land patterns. Otherwise, solder bridging may occur.
- 2. Keep the rated power and ambient temperature within the specified derating curve. Some circuit boards, wiring patterns, temperatures of heat generated by adjacent components, or ambient temper a tures can become factors in the rise of the temperature of the resistors, regardless of the level of power applied. Therefore, check the conditions before use and op timize them so as not to damage the boards and peripheral components.
 - Make sure to contact us before using the resistors under special conditions.
- 3. If a transient load (heavy load in a short time) like a pulse is expected to be applied, check and evaluate the operations of the resistors when installed in your products before use. Never exceed the rated power. Otherwise, the performance and/or reliability of the resistors may be impaired.
- 4. Transient voltage If there is a possibility that the transient phenomenon (significantly high voltage applied in a short time) may occur or that a high voltage pulse may be applied, make sure to evaluate and check the characteristics of resistors mounted on your product rather than only depending on the calculated power limit or steady-state conditions.
- 5. If the resistors are to be used in high frequency circuits, carefully check the operation before use. Such circuits change the electrical characteristics of the resistors.
- 6.Before using halogen-based or other high-activity flux, check the possible effects of the flux residues on the performance and reliability of the resistors.
- 7. When soldering with a soldering iron, never touch the resistors'bodies with the tip of the soldering iron. When using a soldering iron with a high temperature tip, finish soldering as quickly as possible (within three seconds at 350 °C max.).
- 8. Mounting of the resistors with excessive or insufficient wetting amount of solder may affect the connection reliability or the performance of the resistors. Carefully check the effects and apply a proper amount of solder for use.
- 9. When the resistors' protective coatings are chipped, flawed, or removed, the characteristics of the resistors may be impaired. Take special care not to apply mechanical shock during automatic mounting or cause damage during handling of the boards with the resistors mounted.
- 10. Do not apply shock to the resistors or pinch them with a hard tool (e.g. pliers and tweezers). Otherwise, the resistors' protective coatings and bodies may be chipped, affecting their performance.
- 11. Avoid excessive bending of printed circuit boards in order to protect the resistors from abnormal stress.
- 12. Do not immerse the resistors in solvent for a long time.

 Before using solvent, carefully check the effects of immersion.
- 13. Do not apply excessive tension to the terminals.

Panasonic

INDUSTRY

Thick Film Chip Resistors

ERJ type

ERJ XG, 1G, 2G, 3G, 6G series

ERJ 8G, 14, 12, 12Z, 1T series





(Oct. 2021) Products marked as "NRFND" are not recommended for new design.
Target products: ERJ8G, 14, 12, 12Z, 1T series
Please refer to the recommended alternatives with
"Design Support Tool":

Features

Small size and lightweight

• High reliability : Metal glaze thick film resistive element and three layers of electrodes

Compatible with placement machines : Taping packaging available

• Suitable for both reflow and flow soldering

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

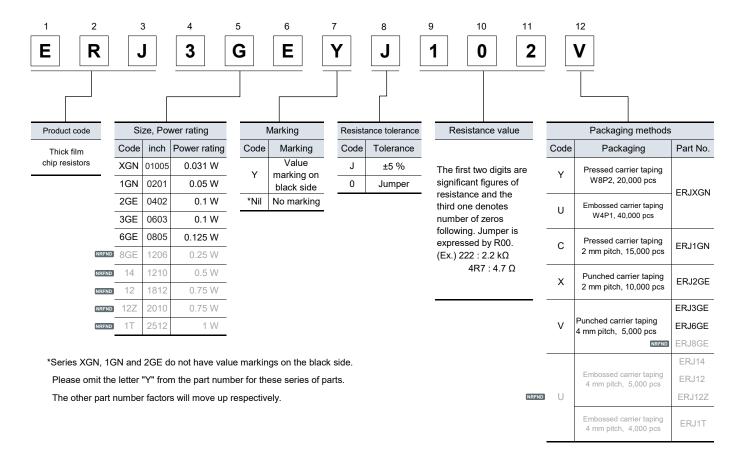
AEC-Q200 compliant (except ERJXG)

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

• ERJXGN, 1GN, 2GE, 3GE, 6GE, 8GE, 14, 12, 12Z, 1T series, ±5 %



Not recommended for new design

Ratings

[For Resistor]

	Part No. nch size)	Rated power*1 (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)		range (×10 ⁻⁶ /K)		AEC- Q200 Grade
((ERJXG 01005)	0.031	15	30	±5	1 to 1 M	(E24)	R<10Ω : -100 to +600 10Ω to $100Ω$: ±300 100Ω≤R : ±200	-55 to +125	-
	ERJ1G 0201)	0.05	25	50	±5	1 to 10 M	(E24)			Grade 1
	ERJ2G 0402)	0.1	50	100	±5	1 to 10 M	(E24)	R<10 Ω : -100 to +600 10 Ω to 1 M Ω : \pm 200		
	ERJ3G 0603)	0.1	75	150	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td>-55 to +155</td><td>Grade 0</td></r>	-55 to +155	Grade 0
	ERJ6G 0805)	0.125	150	200	±5	1 to 10 M	(E24)			
NRFND	ERJ8G 1206)	0.25	200	400	±5	1 to 10 M	(E24)			_
NRFND	ERJ14 1210)	0.5	200	400	±5	1 to 10 M	(E24)	R<10 Ω: -100 to +600		
NRFND	ERJ12 1812)	0.75	200	500	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω : ±200	-55 to +155	Grade 0
NRFND	RJ12Z 2010)	0.75	200	500	±5	1 to 10 M	(E24)	1 M Ω <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
NRFND	ERJ1T 2512)	1	200	500	±5	1 to 1 M	(E24)			

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

Not recommended for new design

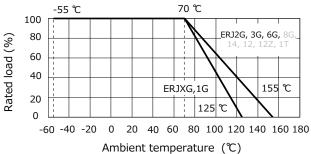
(For Jumper)

	Part No.	Resistance(Ω)	Rated current(A)	Maximum overload current (A)*1
	ERJXG		0.5	1
	ERJ1G ERJ2G ERJ3G		0.5	1
		$50~\text{m}\Omega$ or less	1	2
			1	۷
	ERJ6G		2	4
NR	ERJ8G			
NR	ERJ14			
NRF	ERJ12	$50~\text{m}\Omega$ or less	2	4
NRI	ERJ12Z			
NR	ERJ1T			

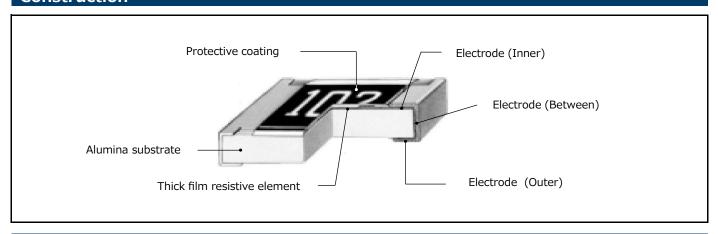
^{* 1 :}Overload test current

Power derating curve

above 70 ℃, power rating shall be derated in accordance with the figure on the right.



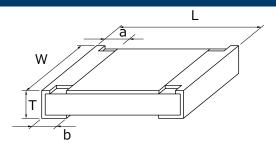
Construction



^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Dimensions (not to scale)



Unit : mm

Part No.		Dimensions										
Part No.	L	W	a	b	Т	(g/1000 pcs)						
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04						
ERJ1G	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15						
ERJ2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8						
ERJ3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2						
ERJ6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4						
NRFND ERJ8G	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10						
NRFND ERJ14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16						
NRFND ERJ12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27						
NRFND ERJ12Z	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27						
NRFND ERJ1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45						

Not recommended for new design

Performance

Test item	Performance re	equirements ⊿R	Test conditions		
rest item	Resistor type Jumper type		rest conditions		
Resistance	Within specified tolerance	50 mΩ or less	20 ℃		
T. C. R.	Within specified T. C. R.	50 mΩ or less	+25℃ / +155℃ (ERJXG,1G : +25℃ / +125℃)		
Overload	±2 %	50 m Ω or less	Rated voltage× 2.5, 5 s Jumper type : Max. overload current, 5 s		
Resistance to soldering heat	±1 %	50 m Ω or less	270 ℃, 10 s		
Rapid change of temperature	±1 %	50 mΩ or less	–55 $^{\circ}$ C (30 min.) / +155 $^{\circ}$ C (ERJXG,1G : +125 $^{\circ}$ C) (30 min.), 100 cycles		
High temperature exposure	±1 %	50 mΩ or less	+155℃ (ERJXG,1G : +125℃), 1000 h		
Damp heat, Steady state	±1 %	50 m Ω or less	60 ℃, 90 % to 95 %RH, 1000 h		
			60 ℃, 90 % to 95 %RH,		
Load life in humidity	±3 %	50 m Ω or less	Rated voltage (Jumper type :Rated current),		
			1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70℃	±3 %	50 mΩ or less	70℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h		

Panasonic

INDUSTRY

Precision Thick Film Chip Resistors

ERJ type

ERJ XG, 1G series

ERJ 1R, 2R, 3R, 6R series

ERJ 3E, 6E, 8E, 14, 12, 1T series





(Oct. 2021) Products marked as "NRFND" are not recommended for new design. Target products: ERJ8E, 14, 12, 1Tseries Please refer to the recommended alternatives with "Design Support Tool".

Features

Small size and lightweight

High reliability : Metal glaze thick film resistive element and three layers of electrodes

Compatible with placement machines : Taping packaging available

Suitable for both reflow and flow soldering

● Low resistance tolerance : ERJXG, 1G, 2R, 3E, 6E, 8E, 14, 12, 1T series : ±1 %

ERJ1R, 2R, 3R, 6R series : ±0.5 %

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

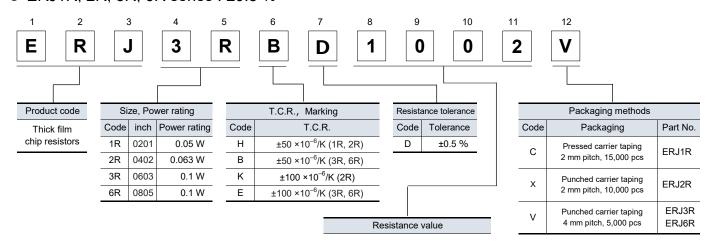
● AEC-Q200 compliant (except ERJXG, ERJ1R)

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

ERJ1R, 2R, 3R, 6R series : ±0.5 %

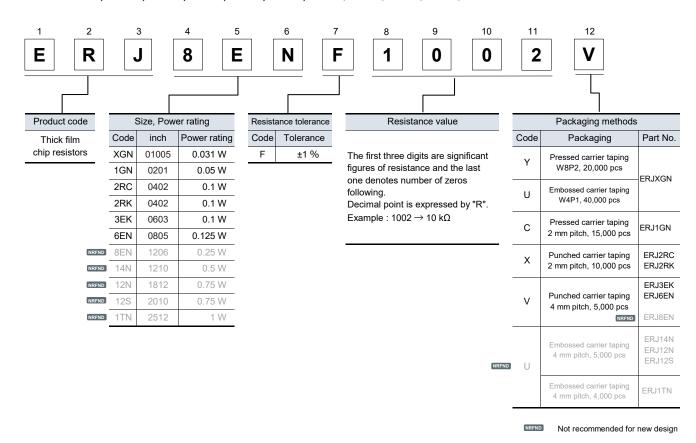


The first three digits are significant figures of resistance and the last one denotes number of zeros following. Example : $1002 \rightarrow 10 \text{ K}\Omega$

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use Should a safety concern arise regarding this product, please be sure to contact us immediately.

Explanation of part numbers

ERJXGN, 1GN, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN series: ±1 %



Ratings

<±0.5 %>

Part No. (inch size)	Rated power ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)		T.C.R. (*10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJ1RH (0201)	0.05	15	30	±0.5	1 k to 1 M	(E24,E96)	±50	-55 to +125	-
ERJ2RH (0402)	0.063	50	100	±0.5	100 to 100 k	(E24,E96)	±50		
ERJ2RK (0402)	0.063	50	100	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	55 to +155	Grade 0
ERJ3RB (0603)	0.1	75 ^{*4}	150 ^{*4}	±0.5	100 to 100 k	(E24,E96)	±50		
ERJ3RE (0603)	0.1	75 ^{*4}	150 ^{*4}	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100		
ERJ6RB (0805)	0.1	150	200	±0.5	100 to 100 k	(E24,E96)	±50		
ERJ6RE (0805)	0.1	150	200	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100		

^{*1 :} Use it on the condition that the case temperature is below the upper category temperature.

^{*2 :} Rated continuous working voltage (RCWV) shall be determined from RCWV=\(\subseteq \text{Power rating} \times \text{Resistance value,} \) or limiting element voltage listed above, whichever less.

^{*3 :} Overload test voltage (OTV) shall be determined from OTV = specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

^{*4 :} UPGRADE

Ratings

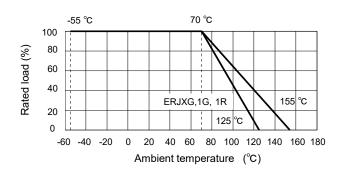
<±1 %>

Part No. (inch size)	Power rating ^{*1} (70 °C) (W)	Limiting element voltage*2 (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJXGN (01005)	0.031	15	30	±1	10 to 1 M ^{*4} (E24,E96)		R < 100 Ω : ±300 100 Ω ≤ R : ±200	-55 to +125	-
ERJ1GN (0201)	0.05	25	50	±1	10 to 1 M ^{*4}	(E24,E96)	±200	-55 to +125	Grade 1
ERJ2RC (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600	-55 to +155	Grade 0
ERJ2RK (0402)	0.1	50	100	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ3EK (0603)	0.1	75	150	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ6EN (0805)	0.125	150	200	±1	10 to 2.2 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ8EN (1206)	0.25	200	400	±1	10 to 2.2 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ14N (1210)	0.5	200	400	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ12N (1812)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ12S (2010)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ1TN (2512)	1	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0

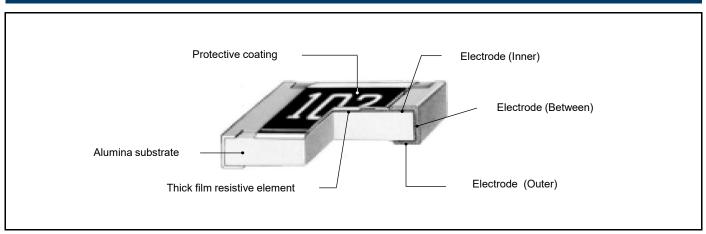
- *1 : Use it on the condition that the case temperature is below the upper category temperature.
- *2 : Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or limiting element voltage listed above, whichever less.
- *3 : Overload test voltage (OTV) shall be determined from OTV = specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.
- *4 : Please contact us when you need a type with a resistance of less than 10 Ω .

Power derating curve

For resistors operated in ambient temperatures above 70 ℃, power rating shall be derated in accordance with the figure on the right.

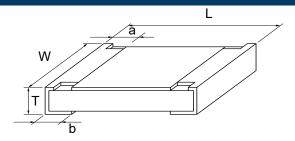


Construction



Not recommended for new design

Dimensions (not to scale)



Part No.			Dimensions (mm)			Mass (Weight)	
Part No.	L	W	а	b	Т	(g/1000 pcs)	
ERJXGN	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04	
ERJ1GN	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15	
ERJ1R□	0.0010.03	0.30±0.03	0.1010.00	0.1010.00	0.2310.03	0.15	
ERJ2R□	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	8.0	
ERJ3R□	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2	
ERJ3EK	1.00±0.10	0.00 10.10/-0.00	0.0010.20	0.00±0.10	0.4010.10		
ERJ6R□	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4	
ERJ6EN	2.0010.20	1.2020.10	0.4010.20	0.4010.20	0.0020.10		
NREND ERJ8EN	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10	
NRFND ERJ14N	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16	
NRFND ERJ12N	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27	
NRFND ERJ12S	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27	
NRFND ERJ1TN	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45	

Not recommended for new design

Performance

• ERJ1R, 2R, 3R, 6R series : ±0.5 % (D)

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload ±2 %		Rated voltage × 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (ERJ1R : +125 ℃)(30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃ (ERJ1R : +125 ℃), 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±2 % ERJ1R : ±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±2 % FRJ1R : +3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

• ERJXGN, 1GN, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN series : ±1 %(F)

Test item	Performance requirements ⊿R	Test conditions		
Resistance	Within specified tolerance	20 ℃		
T. C. R.	Within specified T. C. R.	+25 °C / +155 °C (ERJXG,ERJ1G : +25 °C / +125 °C)		
Overload ±2 %		Rated voltage × 2.5, 5 s		
Resistance to soldering heat	±1 %	270 ℃, 10 s		
Rapid change of temperature	±1 %	–55 ℃ (30 min.)/+155 ℃ (ERJXG,ERJ1G : +125 ℃)(30 min.), 100 cycles		
High temperature exposure	±1 %	+155 ℃ (ERJXG,ERJ1G : +125 ℃), 1000 h		
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h		
Load life in humidity	±2 % ERJXG,1G : ±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 ℃	±2 % ERJXG,1G : ±3 %	70 °C, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		

INDUSTRY



Thin Film Chip Resistors, **High Stability and Reliability Type**

ERA V type

(High resistance value ERA K type)

ERA 2V, 3V, 6V series

(ERA 3K, 6K series)



Features

: To realize higher power rating, Limiting element voltage, and maximum High Power

overload voltage than current products

: Stable at high temperature and humidity High reliability

(85 °C 85 %RH rated load, Category temperature range : -55 °C to +155 °C)

 High accuracy : Low resistance tolerance and temperature coefficient of resistance

 High performance : Low current noise, excellent linearity

Anti-ESD : Original structure for high ESD performance

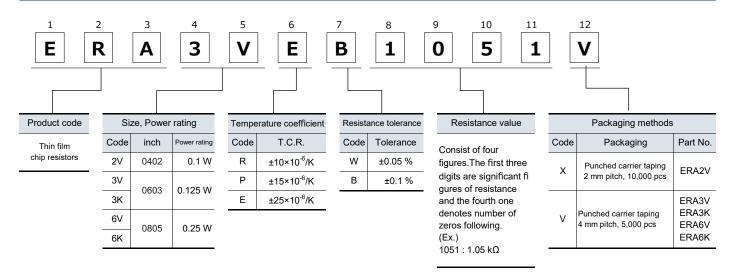
(AEC-Q200-002 HBM Class 1c and above)

 Anti-sulfurated : Original structure for sulfurated performance : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C Reference standard

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers



Thin Film Chip Resistors, High Stability and Reliability Type

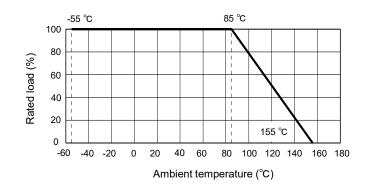
Ratings

Part No. (inch size)	Power rating at 85 ℃ ^{*1} (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Part No. (detail)	Resistance tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Resistance range ^{*4} (Ω)		Category temperature range (°C)	AEC-Q200 Grade
				ERA2VEB	±0.1	±25	47 to 100 k*5	(E24, E96)		
ERA2V	ERA2V (0402) 0.1 75	75	150	ERA2VPB	±0.1	±15				
(0402)		73	130	ERA2VRB	±0.1	±10	1 k to 47 k *5	(E24, E96)		
				ERA2VRW	±0.05	110				
	ERA3V (0603) 0.125	5 100		ERA3VEB	±0.1	±25	47 to 100 k	(E24, E96)		
ERA3V			200	ERA3VPB	±0.1	±15	1 k to 100 k			Grade 0
(0603)				ERA3VRB	±0.1	±10		(E24, E96)		
				ERA3VRW	±0.05					
ERA3K (0603)	0.125	100	200	ERA3KEB	±0.1	±25	102 k to 240 k	(E24, E96)	-55 to +155	Grade 0
				ERA6VEB	±0.1	±25	47 to 100 k	(E24, E96)		
ERA6V	0.25	150	300	ERA6VPB	±0.1	±15				
(0805)	0.23	150	300	ERA6VRB	±0.1	±10	1 k to 100 k	(E24, E96)		
				ERA6VRW	±0.05	±ΙΟ		,		
ERA6K (0805)	0.25	150	300	ERA6KEB	±0.1	±25	102 k to 750 k	(E24, E96)		

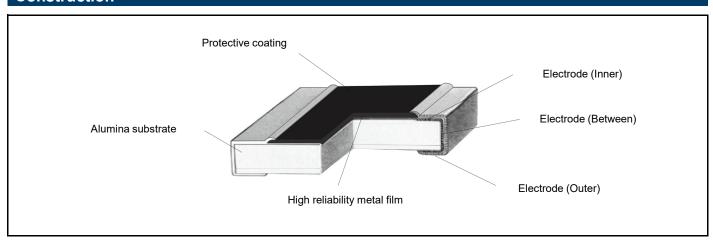
^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

Power derating curve

For resistors operated in ambient temperatures above 85°C, power rating shall be derated in accordance with the figure on the right.



Construction



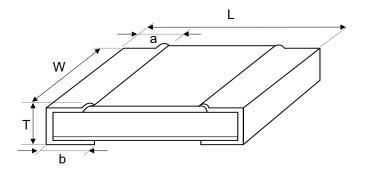
^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) × RCWV or Maximum Overload Voltage listed above, whichever less.

^{*4:} E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.

^{*5:} Expanded resistance range

Dimensions (not to scale)



Unit : mm

Part No.	Dimensions								
Fait No.	L	W	а	b	Т	(g/1000 pcs)			
ERA2V	1.00±0.05	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.35±0.05	0.6			
ERA3V,3K	1.60±0.15	0.80±0.10	0.30±0.20	0.30±0.20	0.45±0.10	2			
ERA6V,6K	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.55±0.10	5			

Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±0.1 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±0.1 %	270 ℃, 10 s
Rapid change of temperature	±0.1 %	-55 °C (30 min.) / +155 °C (30 min.), 1000 cycles
High temperature exposure	±0.1 %	+155 ℃, 1000 h
Damp heat, Steady state	±0.1 %	85 ℃, 85 %RH, 1000 h
Load life in humidity	±0.1 %	85 ℃, 85 %RH, 10 % of Rated power ^{*1} , 1.5 h ON / 0.5 h OFF cycle , 1000 h
Endurance at 85℃	±0.1 %	85 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
		AEC-Q200-002 : 150 pF, 2000 Ω, positive 5 times, negative 5 times
Electro static discharge (HBM)	±0.1 %* ²	ERA2V : 1.0 kV (Class 1c) ERA3V(3K) : 1.5 kV (Class 1c) ERA6V(6K) : 2.0 kV (Class 2)

^{*1:} Applied Voltage is " $\sqrt{0.1 \times \text{Power Rating} \times \text{Resistance Values}}$ ", or "Limiting Element Voltage $\times 0.316$ ", whichever less.

^{*2:} Depends on resistance value.

Panasonic

INDUSTRY

Metal Film (Thin Film) Chip Resistors, High Reliability Type

ERA A type

ERA 1A, 2A, 3A, 6A, 8A series



Features

High reliability : Stable at high temperature and humidity

(85 °C 85 %RH rated load, Category temperature range : –55 °C to +155 °C)

High accuracy : Low resistance tolerance and Temperature Coefficient of Resistance

High performance : Low current noise, excellent linearity

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C

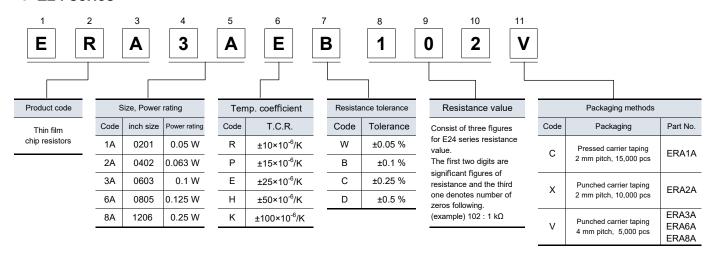
AEC-Q200 compliant (except ERA1A)

RoHS compliant

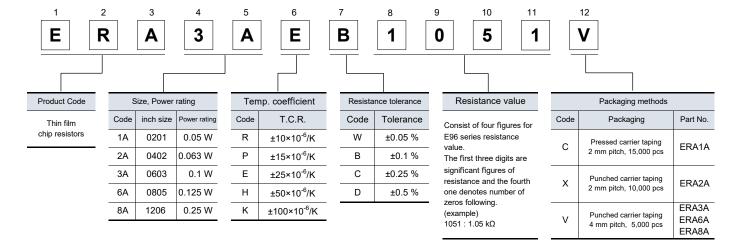
As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

• E24 series



E96 series and other Resistance values



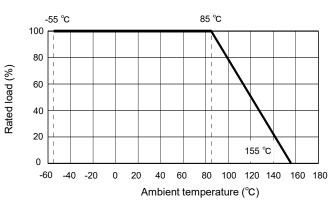
Note: Duplicated resistance values as E24 series part umbers shall follow E24 part numbers. (apply three digit resistance value)

Metal Film (Thin Film) Chip Resistors, High Reliability Type

Ratings Power Limiting Maximum Category Resistance Resistance element overload Part No. T.C.R. AEC-Q200 Part No. rating temperature range*4 *5 tolerance (inch size) voltage*2 voltage*3 (detail) range Grade (85 ℃) (×10⁻⁶/K) (%) (Ω) (\mathcal{C}) (W) (V) (V) **ERA1AEB** ±0.1 ±25 100 to 10 k (E24,E96) ERA1AEC ±0.25 ERA1A ±0.25 0.05 25 50 **ERA1ARC** (0201)(E24,E96) 100 to 10 k **ERA1ARB** ±0.1 ±10 1 k to 10 k (E24,E96) **ERA1ARW** ±0.05 ERA2AKD ±0.5 (E24,E96) ±100 10 to 46.4 ERA2AED ±0.5 **ERA2AEC** ±0.25 ±25 47 to 100 k (E24,E96) ERA2A **ERA2AEB** ±0.1 0.063 100 Grade 1 50 (0402)ERA2APC ±0.25 200 to 47 k ±15 (E24,E96) FRA2APB ±0.1 ERA2ARC ±0.25 ±10 200 to 47 k (E24.E96) **ERA2ARB** ±0.1 ERA3AHD 10 to 46.4 (E24,E96) ±0.5 ±50 **ERA3AED** ±0.5 ERA3AEC ±0.25 ±25 47 to 330 k (E24,E96) ERA3AEB ±0.1 ERA3A ±0.25 0.1 75 150 ERA3APC (0603)470 to 100 k (E24,E96) ±15 **ERA3APB** ±0.1 **ERA3ARC** ±0.25 -55 to +155 **ERA3ARB** 1 k to 100 k (E24,E96) ±0.1 ±10 **ERA3ARW** ±0.05 ERA6AHD (E24,E96) ±0.5 ±50 10 to 46.4 ERA6AED ±0.5 ERA6AEC ±0.25 47 to 1 M +25 (E24.E96) ERA6AEB ±0.1 ERA6A 0.125 100 200 ERA6APC ±0.25 Grade 0 (0805)470 to 100 k ±15 (E24,E96) **ERA6APB** ±0.1 **ERA6ARC** ±0.25 **ERA6ARB** 1 k to 100 k ±0.1 ±10 (E24,E96) **ERA6ARW** ±0.05 ERA8AHD ±0.5 (E24,E96) 10 to 46.4 ±50 ERA8AED ±0.5 ERA8AEC ±0.25 ±25 47 to 1 M (E24,E96) **ERA8AEB** ±0.1 ERA8A 0.25 150 300 FRA8APC ±0.25 (1206)470 to 100 k ±15 (E24,E96) **ERA8APB** ±0.1 ERA8ARC ±0.25 ERA8ARB ±0.1 ±10 1 k to 100 k (E24,E96) ERA8ARW ±0.05

Power derating curve

For resistors operated in ambient temperatures above 85 °C, power rating shall be derated in accordance with the figure on the right.



^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

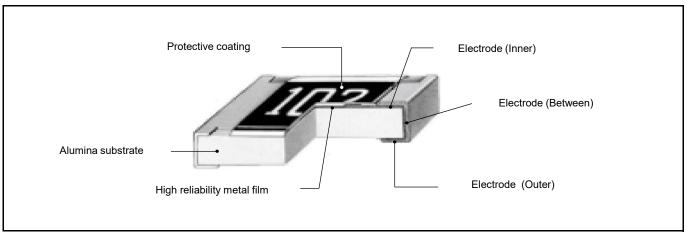
^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) × RCWV or Maximum Overload Voltage listed above, whichever less.

^{*4:} E192 series resistance values are also available. Please contact us for details.

^{*5:} Duplicated resistance values between E96, E192 and E24 series shall follow E24 Part Numbers. (apply three digit resistance value)

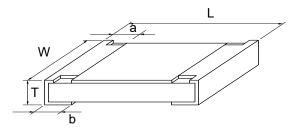
Metal Film (Thin Film) Chip Resistors, High Reliability Type

Construction



^{*0201/0402} size or E96 series do not have value markings.

Dimensions (not to scale)



Unit : mm

Part No. Dimensions						Mass (Weight)
Fait No.	L	W	а	b	Т	(g/1000 pcs)
ERA1A	0.60±0.03	0.30±0.03	0.15±0.05	0.15±0.05	0.23±0.03	0.14
ERA2A	1.00±0.10	0.50+0.10/-0.05	0.15±0.10	0.25±0.10	0.35±0.05	0.6
ERA3A	1.60±0.20	0.80±0.20	0.30±0.20	0.30±0.20	0.45±0.10	2
ERA6A	2.00±0.20	1.25±0.10	0.40±0.25	0.40±0.25	0.50±0.10	4
ERA8A	3.20±0.20	1.60+0.05/-0.15	0.50±0.25	0.50±0.25	0.60±0.10	8

Performance

Test Item	Performance	Test conditions
rest item	requirements ⊿R	r est conditions
Resistance	Within specified	20 ℃
Resistance	tolerance	20 C
T. C. R.	Within specified	+25 ℃ / +125 ℃
1. U. N.	T. C. R.	+25 C/+125 C
Overload	R<47 Ω : ±0.5 %	Datad voltage v 2.5.5 c
Overload	R≧47Ω : ±0.1 %	Rated voltage x 2.5, 5 s
Resistance to	R<47 Ω : ±0.5 %	270 °C 10 a
soldering heat	R≧47Ω : ±0.1 %	270 ℃, 10 s
Rapid change	R<47 Ω: ±0.5 %	ERA1A, 2A: -55 ℃ (30 min.) / +125 ℃ (30 min.),1000 cycles
of temperature	R≧47Ω : ±0.1 %	ERA3A, 6A, 8A : –55 ℃ (30 min.) / +155 ℃ (30 min.),1000 cycles
High temperature	R<47 Ω: ±0.5 %	1155 ℃ 1000 b
exposure	R≧47Ω : ±0.1 %	+155 ℃, 1000 h
Damp heat,	R<47 Ω: ±0.5 %	05 °C 05 0/ DIL 4000 b
Steady state	R≧47Ω : ±0.1 %	85 ℃, 85 %RH, 1000 h
I oad life in	R<47 Ω : ±0.5 %	85 ℃, 85%RH, 10% rated power, 1.5 h ON / 0.5 h OFF cycle, 1000 h,
humidity	R≥470: +0.1 %	Max. test voltage : ERA2A : 15.8 V, ERA3A : 23.7 V, ERA6A : 31.6 V,
	T(=+122. ±0.1 /0	ERA8A : 47.4 V
Endurance at 85℃	R<47 Ω : ±0.5 %	95°C Potod voltage 1.5 h ON / 0.5 h OFF evals 1000 h
	R≧47Ω : ±0.1 %	85℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Panasonic

INDUSTRY

High Precision Thick Film Chip Resistors

ERJ PB type

ERJ PB3, PB6 series



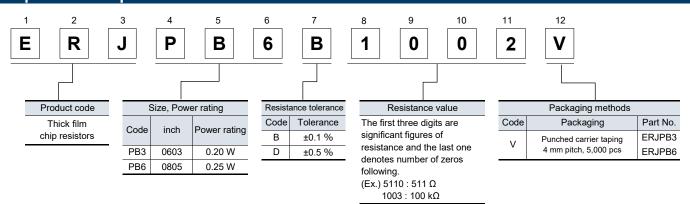
Features

- Achieve the resistance tolerance ±0.1 % with high reliability metal glaze thick film resistor
- Guarantee the temperature coefficient of Resistance ±50×10⁻⁶/K in high resistance range up to 1 MΩ
- High power : 0.20 W : 0603 inch /1608 mm size(ERJPB3)

: 0.25 W: 0805 inch /2012 mm size(ERJPB6)

- Reference Standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers



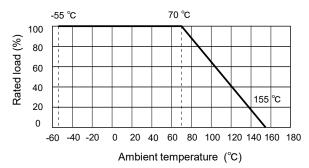
Ratings

Part No. (inch size)	Power rating ^{*1} (70 °C)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJPB3 (0603)	0.20	150	200	±0.1 ±0.5	200 to 100 k (E24, E96)	±50	55 to ±155	Crado 0
ERJPB6 (0805)	0.25	150	200	±0.1 ±0.5	200 to 1 M (E24, E96)	±50	-55 to +155	Grade 0

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

Power derating curve

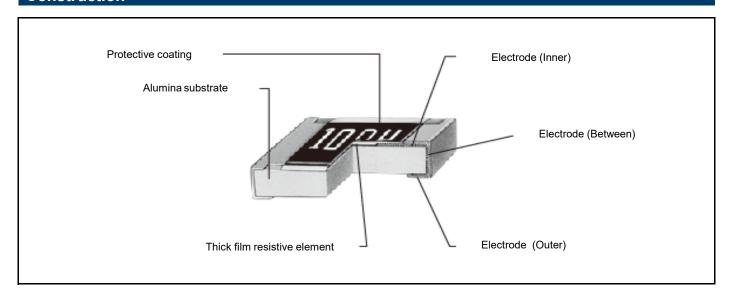
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



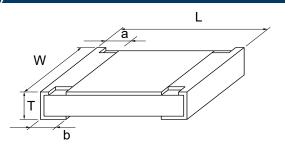
^{*2:} Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum overload voltage listed above, whichever less.

Construction



Dimensions (not to scale)



Unit : mm

Part No.	Dimensions					
Fait No.	L	W a		b	Т	(g/1000 pcs)
ERJPB3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2
ERJPB6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4

Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±0.5 %	Rated voltage× 2.0, 5 s
Resistance to soldering heat	±0.5 %	270 ℃, 10 s
Rapid change of temperature	±0.5 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High temperature exposure	±0.5 %	+155 ℃, 1000 h
Damp heat, Steady state	±0.5 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±0.5 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±0.5 %	70 ℃, Rated voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h

Panasonic

INDUSTRY

Thick Film Chip Resistors (Low Resistance Type)

ERJ type

ERJ 2LW, 3LW, 6LW series

ERJ 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series

ERJ 2B, 3B, 6D, 6B, 8B, 14B series

ERJ 3R, 6R, 8R, 14R, 12R, 12Z, 1TR series

ERJ L03, L06, L08, L14, L12, L1D, L1W series



- Current sensing resistor
- Small size and lightweight
- Realize both low-resistance & High-precision by original thick film resistive element & special electrode structure
- Suitable for both reflow and flow soldering
- Realize High-power by double-sided resistive elements structure that aimed to suppress temperature rising

: ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW

* RET! SO!

● Low TCR : ±75×10⁻⁶/K(ERJ6CW, ERJ8CW)

• Low resistance value : Thick film resistors available from 5 mΩ (ERJ3LW, 6LW)

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2144

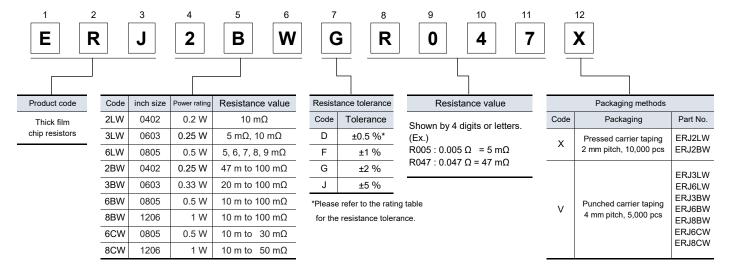
AEC-Q200 compliant

RoHS compliant

As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

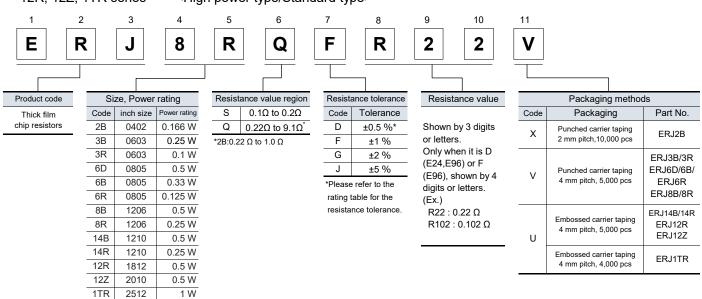
Explanation of part numbers

ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series
 High power (double-sided resistive elements structure) type>

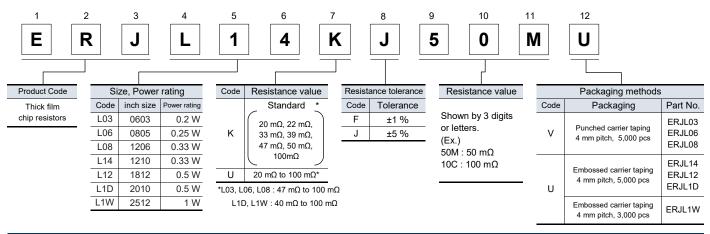


Explanation of part numbers

• ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, <High power type/Standard type> 12R, 12Z, 1TR series



ERJL03, L06, L08, L14, L12, L1D, L1W series <Low TCR type>



Ratings

<High power (double-sided resistive elements structure) type>

Part No. (inch size)	Power rating (70 °C) ^{*1} (W)	Resistance tolerance (%)	Resistance range ^{*2} (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ2LW (0402)	0.2	±1, ±2, ±5	10 m	0 to +500		
ERJ3LW (0603)	0.25	±1, ±2, ±5	5 m	0 to +700	-55 to +125	Grade 1
L1(00LVV (0000)	0.23	±1, ±2, ±0	10 m	0 to +300	-00 to 1120	Grade 1
ERJ6LW (0805)	0.5	±1, ±2, ±5	5, 6, 7, 8, 9 m	0 to +300		
ERJ2BW (0402)	0.25	±1, ±2, ±5	47 m to 100 m (E24)	0 to +300		
ERJ3BW (0603)	0.33	±1, ±2, ±5	20 m to 100 m (E24)	$20 \text{ m}\Omega \le R < 39 \text{ m}\Omega : 0 \text{ to } +250$		
LINDSDVV (0003)	0.55	11, 12, 13	20 111 10 100 111 (E24)	$39 \text{ m}\Omega \leq R \leq 100 \text{ m}\Omega : 0 \text{ to } +150$		
ERJ6BW (0805)	0.5	±1, ±2, ±5	10 m to 100 m (E24)	$10 \text{ m}\Omega \le R < 15 \text{ m}\Omega_{:0 \text{ to } +300}$	-55 to +155	Grade 0
LINDDVV (0003)	0.5	11, 12, 13	10 111 10 100 111 (E24)	$15 \text{ m}\Omega \leq R \leq 100 \text{ m}\Omega : 0 \text{ to } +200$	-55 10 +155	Grade 0
				10 mΩ ≤ R < 20 mΩ :0 to +200		
ERJ8BW (1206)	1	±1, ±2, ±5	10 m to 100 m (E24)	$20 \text{ m}\Omega \le R < 47 \text{ m}\Omega : 0 \text{ to } +150$		
				$47 \text{ m}\Omega \le R \le 100 \text{ m}\Omega : 0 \text{ to } +100$		
ERJ6CW (0805)	0.5	±0.5, ±1, ±2, ±5	10 m to 30 m (E24)	±75	-55 to +125	Crada 1
ERJ8CW (1206)	1	±1, ±2, ±5	10 m to 50 m (E24)	±75	-55 10 +125	Grade 1

^{*1:} Use it on the condition that the case temperature is below the upper category temperature

[•] Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(\sqrt{Power Rating} \times \text{Resistance Value}.\)

[·] Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

^{*2:} Please contact us when resistors of irregular series are needed.

Thick Film Chip Resistors (Low Resistance Type)

Ratings

<High power type>

Part No. (inch size)	Power rating (70 °C) ^{*1} (W)	Resistance tolerance*2 (%)	Resistand range ^{*3} (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ2BS (0402)	0.166	±1 ±2 ±5	0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +300$		
ERJ2BQ (0402)	0.100	±1, ±2, ±5	0.22 to 1.0	(E24)	$0.22~\Omega \le R \le 1.0~\Omega~:0$ to +250		
ERJ3BS (0603)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +300$		
ED 12DO (0602)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \le R < 1.0~\Omega~: 0 \text{ to } +300$		
ERJ3BQ (0603)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ6DS (0805)			0.10 to 0.20	(E24,E96)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +150$		
ERJ6DQ (0805)	0.5	±0.5, ±1, ±2, ±5	0.22 to 9.1	(E24,E96)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +100$		
EKJODQ (0003)				(E24,E96)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ6BS (0805)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$	-55 to +155	Grade 0
ED ISDO (0905)	0.33	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$		
ERJ6BQ (0805)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ8BS (1206)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$		
ED 10DO (1206)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \le R < 1.0~\Omega~: 0 \text{ to } +250$		
ERJ8BQ (1206)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ14BS (1210)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ14BQ (1210)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \le R < 1.0~\Omega~: 0 \text{ to } +200$		
LN314BQ (1210)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±100		

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

<Standard type>

Part No. (inch size)	Power rating (70 °C) ^{*1} (W)	Resistance tolerance (%)	Resistand range $^{^{\star 2}}$ (Ω)	e	T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ3RS (0603)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +300$		
ERJ3RQ (0603)	0.1	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +300$		
LN33NQ (0003)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±200		
ERJ6RS (0805)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$		
ERJ6RQ (0805)	0.125	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$		
LINUINQ (0003)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±200		
ERJ8RS (1206)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$		
ERJ8RQ (1206)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$		
LINJOINQ (1200)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±200		
ERJ14RS (1210)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ14RQ (1210)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \sim +200$	-55 to +155	Grade 0
LN314NQ (1210)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±100		
ERJ12RS (1812)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ12RQ (1812)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$		
LIN0121NQ (1012)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ12ZS (2010)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ12ZQ (2010)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$		
ERJ 122Q (2010)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ1TRS (2512)			0.10 to 0.20	(E24)	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +200		
ERJ1TRQ (2512)	1	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$		
(2512)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±100		

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

^{*2:} E96 series also have ± 0.5 %, ± 1 % line-up.

[•] Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(\sqrt{Power Rating \times Resistance Value.} \)

[·] Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

^{*3:} Please contact us when resistors of irregular series are needed.

[•] Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating × Resistance Value.

[·] Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

^{*2:} Please contact us when resistors of irregular series are needed.

Thick Film Chip Resistors (Low Resistance Type)

Ratings

<Low TCR type>

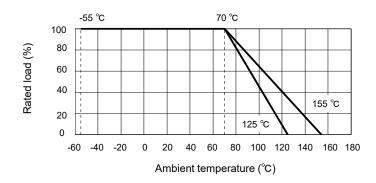
Part No. (inch size)	Power rating (70 °C) ^{*1} (W)	Resistance tolerance (%)	Resistance range ^{*2} (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJL03 (0603)	0.2	±1, ±5	47 m to 100 m	±200		
ERJL06 (0805)	0.25	±1, ±5	47 m to 100 m	±100		
ERJL08 (1206)	0.33	±1, ±5	47 m to 100 m	±100		
ERJL14 (1210)	0.33	±1, ±5	20 m to 100 m		-55 to +125	Grade 1
ERJL12 (1812)	0.5	±1, ±5	20 m to 100 m	R < 47 mΩ : ±300		
ERJL1D (2010)	0.5	±1, ±5	40 m to 100 m	R ≥ 47 mΩ : ±100		
ERJL1W (2512)	1	±1, ±5	40 m to 100 m			

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

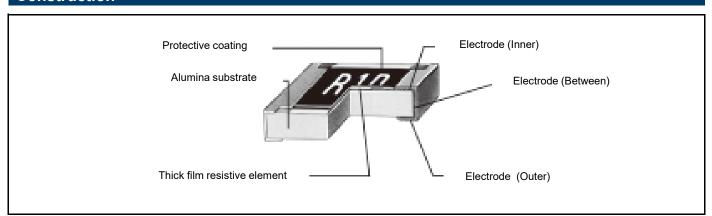
- Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.
- · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- *2: Standard R.V. : $20~m\Omega$, $22~m\Omega$, $33~m\Omega$, $39~m\Omega$, $47~m\Omega$, $50~m\Omega$, $100~m\Omega$, Custom R.V. : Each $1~m\Omega$ within upper range.

Power derating curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

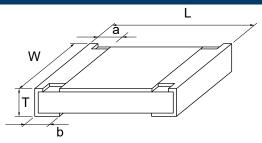


Construction



Thick Film Chip Resistors (Low Resistance Type)

Dimensions (not to scale)



	T					Unit : mm
Part No.			Dimensions	T	T	Mass (Weight)
	L	W	а	b	Т	(g/1000 pcs)
ERJ2LW	1.00±0.10	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.40±0.05	8.0
ERJ2BW	1.00±0.10	0.50+0.10/-0.05	0.24±0.10	0.24±0.10	0.35±0.05	0.8
ERJ2B	1.00±0.10	0.50+0.10/-0.05	0.20±0.10	0.27±0.10	0.35±0.05	0.8
ERJ3LW (5 m Ω)	1.60±0.15	0.80±0.15	0.50±0.20	0.50±0.20	0.55±0.10	3
ERJ3LW (10 mΩ) ERJ3BW	1.60±0.15	0.80±0.15	0.40±0.20	0.40±0.20	0.55±0.10	3
ERJ3R ERJ3B ERJL03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2
ERJ6LW	2.00±0.20	1.25±0.20	0.63±0.20	0.63±0.20	0.70±0.10	6
ERJ6BW	2.00±0.20	1.25±0.20	0.55±0.20	0.55±0.20	0.65±0.10	6
ERJ6CW (10 to 13 mΩ)	0.05.0.00	4.00.0.00	0.60±0.20	0.60±0.20	0.05.0.40	
ERJ6CW (15 to 30 mΩ)	2.05±0.20	1.30±0.20	0.45±0.20	0.45±0.20	0.65±0.10	6
ERJ6D	2.00±0.20	1.25±0.10	0.40±0.20	0.55±0.25	0.60±0.10	5
ERJ6R ERJ6B ERJL06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	5
ERJ8BW	3.20±0.20	1.60±0.20	1.00±0.20	1.00±0.20	0.65±0.10	13
ERJ8CW (10 to 16 mΩ)	3.20±0.20	1.60±0.20	1.10±0.20	1.10±0.20	0.65±0.10	13
ERJ8CW (18 to 50 mΩ)	3.20±0.20	1.60±0.20	0.60±0.20	0.60±0.20	0.65±0.10	13
ERJ8R ERJ8B ERJL08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10
ERJ14R ERJ14B ERJL14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16
ERJ12R ERJL12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27
ERJ12Z ERJL1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27
ERJ1TR	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45
ERJL1W	6.40±0.20	3.20±0.20	0.65±0.20	1.30±0.20	1.10±0.10	79

Performance

• ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series <High power (double-sided resistive elements structure) type>

Test item	Performance requirements ⊿R	Test conditions		
Resistance	Within specified tolerance	20 ℃		
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃		
Overload	±2 %	ERJ6LW : Rated voltag× 1.77, 5 s ERJ8BW (R > 0.05 Ω) : Rated voltag× 1.77, 5 s Other : Rated voltag× 2.0, 5 s		
Resistance to soldering heat	±1 %	270 ℃, 10 s		
Rapid change of temperature	±1 % ERJ2LW : ±2 %	–55 ℃ (30min.) / +155 ℃ (ERJ□LW, ERJ□CW : +125 ℃) (30 min.), 100 cycles		
High temperature exposure	±1 %	+155 ℃ (ERJ□LW, ERJ□CW : +125 ℃), 1000 h		
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h		
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		

• ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR series <High power type/Standard type>

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	Rated voltage× 2.5 (ERJ6D : ×1.77), 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

● ERJL03, L06, L08, L14, L12, L1D, L1W series < Low TCR type >

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +125 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+125 ℃, 1000 h
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Panasonic

INDUSTRY

Current Sensing Resistors, Metal Plate Type

ERJ MS, MB type

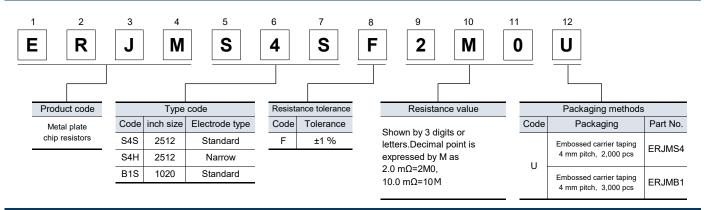
ERJ MS4, MB1 series



Features

- Ideal for current sensing solution
- Small case size with high power
- Metal plate bonding technology. Excellent long term stability
- Outer Resin with high heat dissipation. Wide temperature range (-65 °C to +170 °C)
- AEC-Q200 compliant
- RoHS compliant
- ISO9001, ISO/TS16949 certified
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers



Ratings							
Part No. (inch size)	Power rating (70 ℃) (W)	Resistance range (mΩ)	Resistance tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	Terminal temp. upper limit (℃)	AEC-Q200 Grade
ERJMS4S (2512)	3	1, 2, 3, 4	F:±1	±75		130	
ERJMS4H	3	5, 6	F:±1	±75	_65 to +170		Grade 0
(2512)	2	7, 8, 9, 10	F:±1	±75	-03 10 +170	100	Grade 0
ERJMB1S (1020)	2	1, 2, 3, 4, 5	F : ±1	±75		130	

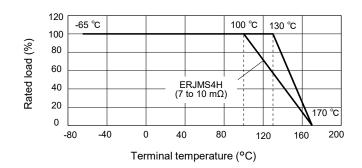
^{*} Please contact us when resistors of irregular series are needed.

Power derating curve

If the terminal temperature of the resistor is more than terminal temperature upper limit value of the rated table, please reduce the rated power according to the Power Derating Curve shown in the figure on the right. <Supplemented>

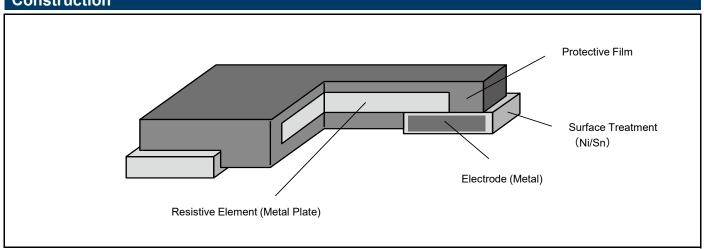
In the case of the temperature measurement of the terminal portion of the resistor, Please perform under the following conditions.

- Terminal temperature measurement, please apply the temperature of the higher of either the left or right electrode upper surface of the resistor.
- Please measure the temperature of the resistor in the land pattern printed of circuit board and plan to use by real conditions.



Current Sensing Resistors, Metal Plate Type

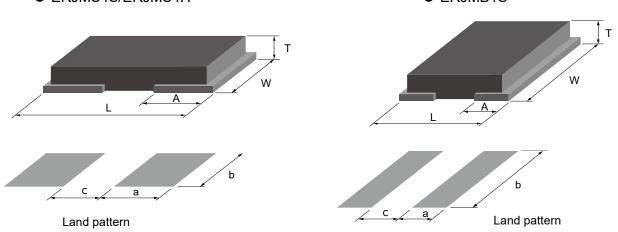
Construction



Dimensions in mm (not to scale), Recommended land pattern







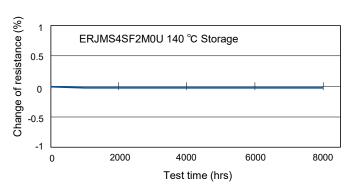
Unit : mm

Part No.		Dime	Recom	Mass (Weight)				
	L	W	Α	Т	а	b	С	(g/1000 pcs)
ERJMS4S	6.40±0.25	3.20±0.25	2.20±0.25	1.20±0.15	2.7	3.4	2.0	120
ERJMS4H	6.40±0.25	3.20±0.25	1.25±0.25	1.20±0.15	1.7	3.4	4.0	115
ERJMB1S	2.55±0.25	5.00±0.25	0.68 +0.15/-0.20	0.90±0.15	1.15	5.5	1.1	40

Typical temp. dependence of electrical resistance

Change of resistance (%) 0.5 0 -0.5 -80 -60 -40 -20 20 40 60 80 100 120 140 160 180 Temperature (°C)

Long-term stability



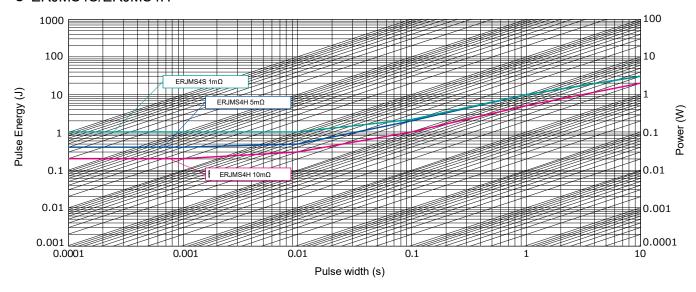
Maximum pulse energy respectively pulse power for continuous operation

Referance Data

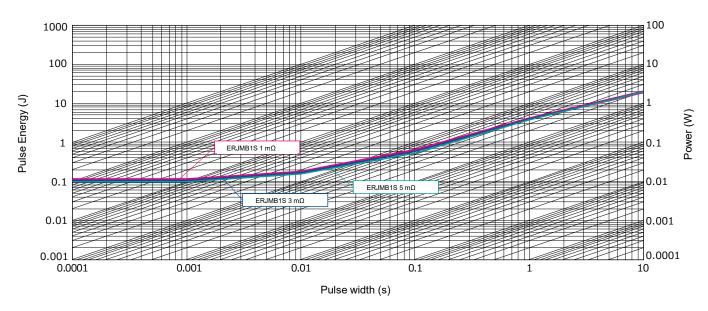
Condition: Room Temperature, OFF: 10 s, 1000 cycle, Wave form: Square

Change of Resistance = ±1 %

ERJMS4S/ERJMS4H



• ERJMB1S



Performance (AEC-Q200)

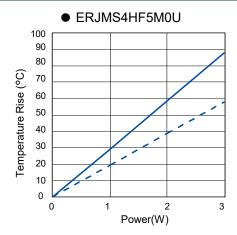
ERJMS4S/ERJMS4H

Test item	Performance requirements ⊿R	Typical value ⊿R	Test condition
Thermal shock	±1 %	0.20 %	-55 ℃ / +155 ℃, 1000 cycles
Overload	±0.5 %	0.10 %	Rated power x 3, 5 s
Solderability	> 95% coverage	> 95% coverage	245 ℃, 3 s
Resistance to solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low temperature storage and operation	±0.5 %	0.03 %	–65 ℃, 24 h
Resistance to soldering heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 ℃, 10 s)
Moisture resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 ℃, Rated Power, 2000 h
Storage life at elevated temperature	±1 %	0.30 %	170 ℃, 2000 h
High temperature characteristics	±0.5 %	0.05 %	140 ℃, 2000 h
Frequency characteristics	< 5 nH	< 2 nH	Inductance

ERJMB1

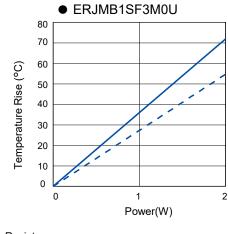
Test item	Performance requirements ⊿R	Typical value ⊿R	Test condition
Thermal shock	±1 %	0.30 %	-55 ℃ / +155 ℃, 1000 cycles
Overload	±1 %	0.30 %	Rated power x 2.5, 5 s
Solderability	> 95% coverage	> 95% coverage	245 ℃, 3 s
Resistance to solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low temperature storage and operation	±0.5 %	0.03 %	–65 ℃, 24 h
Resistance to soldering heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 ℃, 10 s)
Moisture resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 ℃, Rated Power, 2000 h
Storage life at elevated temperature	±1 %	0.30 %	170 ℃, 2000 h
High temperature characteristics	±0.5 %	0.05 %	140 ℃, 2000 h
Frequency characteristics	< 5 nH	< 2 nH	Inductance

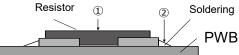
Temperature rise



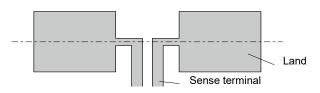
<Condition>

Base material: FR-4 (t 1.6 mm) Copper Thickness : 70 µm, Two layer





Sense terminal-Layout



Panasonic

INDUSTRY



High Power Chip Resistors (Wide Terminal Type)

ERJ A, B type

ERJ A1, B1, B2, B3 series

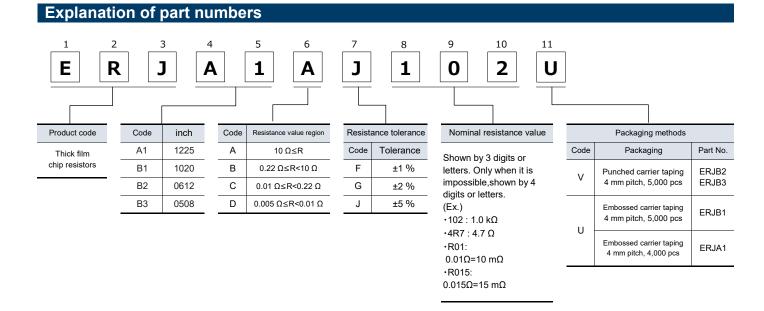


Features

- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.



High Power Chip Resistors (Wide Terminal Type)

Ratings

Part No. (inch size)	Power rating*1 (W)	Rated ambient temperature*2	Rated terminal part temperature*2	Limiting element voltage ^{*3} (V)	Maximum overload voltage ^{*4} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade					
ERJA1	1.33	70	_	200			000 400		200 400		100m to 10k (E24)	±100			
(1225)	1.33	70	-	200	400	±2, ±5	10m to 10k (E24)	10mΩ≤R<100mΩ : ±350 100mΩ≤R≤10kΩ : ±200							
						±1		Resistance tolerance $\pm 1 \%$: $10m\Omega \le R < 22m\Omega : 0 \text{ to } +350$							
ERJB1	2 (R≤10Ω)	70	125			±2, ±5	10m to 10 (E24)	22mΩ≤R<47mΩ : 0 to +200 47mΩ≤R<100mΩ : 0 to +150							
(1020)				200	400			100mΩ≤R≤10kΩ : ±100 Resistance tolerance±2 %, ±5 % :							
	1	70	0.5			±1	10 to 10k	10mΩ≤R<22mΩ : 0 to +350							
	(R>10Ω)	70	95								±2, ±5	(E24)	22mΩ≤R<100mΩ : 0 to +200		
						12, 13		100mΩ≤R≤10kΩ :±200							
	1.5	_	125			±1	10m to 1k	Resistance tolerance ±1 %:							
	(R≤1kΩ)					±2, ±5	(E24)	10mΩ≤R<22mΩ : 0 to +300							
									±1	10m to 1k	22mΩ≤R<47mΩ : 0 to +200	−55 ~ +155	Grade 0		
								±2	(E24)	47mΩ≤R<100mΩ : 0 to +150	-55 ~ +155	Graue 0			
								100mΩ≤R≤220mΩ : 0 to +100							
ERJB2 (0612)	1 (R≤1kΩ)	70	-	200	400		5, 6, 7, 8,	220mΩ≤R≤1MΩ : ±100 Resistance tolerance ±2 %, ±5 % :							
(0012)	(11211132)					±5	9,10m to 1M	Resistance tolerance ±2 %, ±5 % . $5m\Omega \le R < 22m\Omega : 0 \text{ to } +300$							
							(E24)	$22m\Omega \le R < 47m\Omega : 0 \text{ to } +200$							
								$47m\Omega \le R < 100m\Omega : 0 \text{ to } +150$							
	0.75					±1	1k to 1M	100mΩ≤R<220mΩ : 0 to +200							
	(R>1kΩ)	70	90			±2, ±5	(E24)	220mΩ≤R≤1MΩ : ±200							
						±1		Resistance tolerance ±1%:							
	1	-	105				20m to 10	20mΩ≤R<47mΩ : 0 to +300							
						±2, ±5	(E24)	47mΩ≤R<1Ω : 0 to +200							
ERJB3	0.5			150 200	150 200	150 200	200	150 200	150 200	±1	20m t- 1	1Ω≤R≤10Ω : ±100			
(0508)	0.5 (R≤1Ω)	70	-				200			200	200	200	±2, ±5	20m to 1 (E24)	Resistance tolerance ±2 %, ±5 %:
	0.33					±1	1 to 10	$20m\Omega \le R < 47m\Omega : 0 \text{ to } +300$ $47m\Omega \le R < 1\Omega : 0 \text{ to } +200$							
	0.33 (R>1Ω)	70	-			±2, ±5	(E24)	1Ω≤R≤10Ω : ±200							

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

^{*2:} If there is a doubt whether the rated ambient temperature or the rated terminal part temperature is used, give priority to the rated terminal part temperature.

^{*3:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

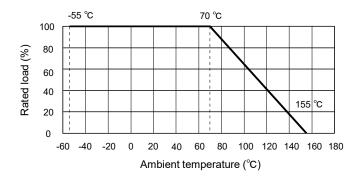
^{*4:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Ratings

Power derating curve

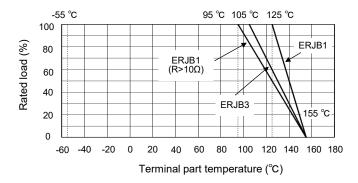
• For resistors operated in ambient rated ambient temperature, power rating shall be derated in accordance with the figure below.

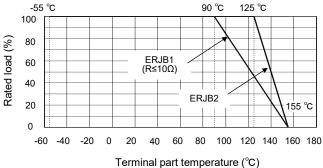
In addition, please use under the condition that the product temperature is below the upper category temperature.



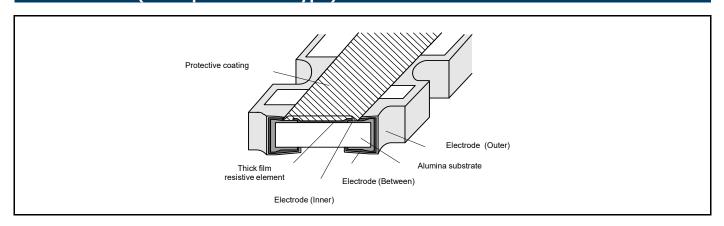
• For resistors operated in ambient rated terminal part temperature, power rating shall be derated in accordance with the figure below.

In addition, please use under the condition that the product temperature is below the upper category temperature.



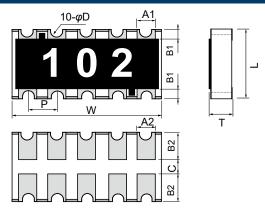


Construction (Example : ERJA1 type)



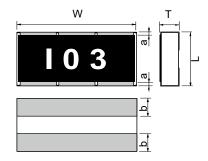
High Power Chip Resistors (Wide Terminal Type)

Dimensions (not to scale)



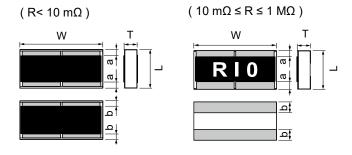
Unit : mm

Part No.		Dimensions					
Fait No.	L	W	A ₁	B ₁	Т	(g/1000 pcs)	
	3.20±0.20	6.40±0.20	0.70±0.20	0.45±0.20	0.55±0.10		
ERJA1	A_2	B_2	Р	øD	С	40	
	0.70±0.20	1.25±0.15	1.27±0.10	0.30+0.10/-0.20	0.4 min.		



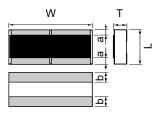
Unit : mm

Part No.		Dimensions						
Fait No.	L	L W a b				(g/1000 pcs)		
ERJB1	2.50±0.20	5.00±0.20	0.25±0.20	0.90±0.20	0.55±0.20	27		



Unit : mm

Part No.		Dimensions				
ERJB2	L	W	а	b	T	(g/1000 pcs)
5 mΩ≤R<10 mΩ			0.30±0.20	0.30±0.20	0.65±0.15	
10 mΩ≤R<220 mΩ	1.60±0.15	3.20±0.20	0.30±0.20	0.50+0.20	0.55±0.15	11
220 mΩ≤R≤1 MΩ			0.25±0.20	0.50±0.20	0.55±0.15	

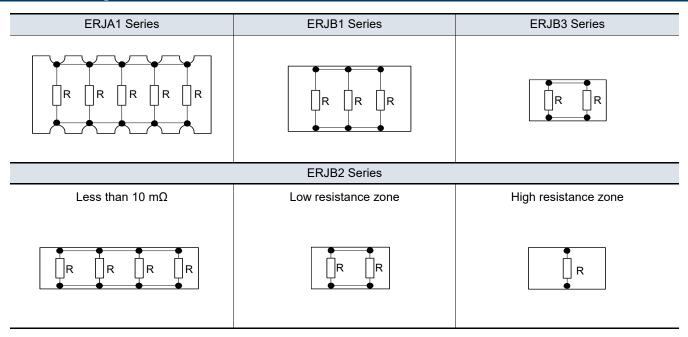


Unit: mm

Part No.	Dimensions					
Fait No.	L	W	а	b	Т	(g/1000 pcs)
ERJB3	1.25±0.10	2.00±0.15	0.25±0.20	0.40±0.20	0.50±0.10	4.8

High Power Chip Resistors (Wide Terminal Type)

Circuit configuration



Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	ERJA1, ERJB1 (R>10) : Rated voltag× 2.5, 5 s ERJB2 (R>1kΩ) : Rated voltag× 2.2, 5 s ERJB1 (R≤10), ERJB2 (R≤1kΩ), ERJB3 : Rated voltag× 2.0, 5 s
Resistance to soldering heat	±1 %	270℃, 10 s
Rapid change of temperature	±2 %	-55 ℃ (30 min.) / +125 ℃ (30 min.), 1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity 1 (Applicable to rated ambient temperature-regulated products)	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage 1.5 h ON / 0.5 h OFF cycle, 1000 h
Load life in humidity 2 (Applicable to rated ambient temperature-regulated products)	±3 %	85 °C, 85 %RH, Rated power 10%, Continuously power, 1000 h
Durability at rated ambient temperature or rated terminal part temperature	±3 %	Rated ambient temperature or rated terminal part temperature, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Low TCR High Power Chip Resistors (Wide Terminal Type)

.010

ERJ D type

ERJ D1, D2 series

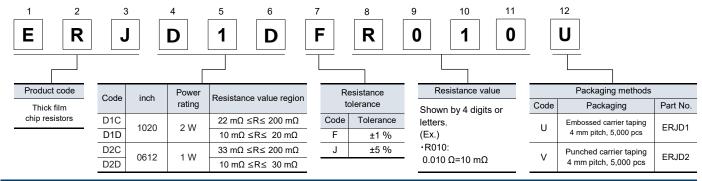
Features

- Achieved High power and low TCR (±100×10⁻⁶/K) using wide terminal electrode structure and original material
- Suitable for small size/high power current detection (Low TCR enables high accuracy of current detection)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers



Ratings

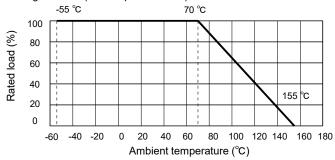
Part No. (inch size)	Power rating (70 ℃)*1 (W)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJD1 (2550)	2	±1, ±5	10 m to 200 m (E24)	±100	-55 to +155	Grade 0
ÉRJD2 (1632)	1	±1, ±5	10 m to 200 m (E24)	±100	-55 10 +155	Grade 0

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

- · Please contact us when resistors of irregular series are needed.
- Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.
- · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV.

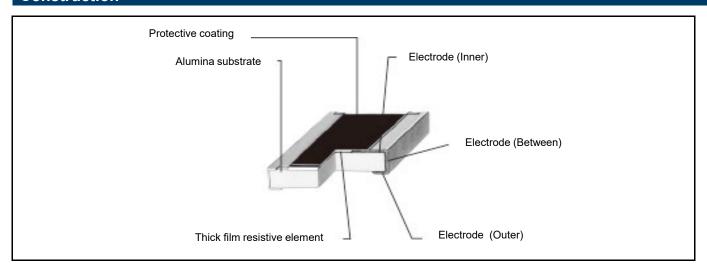
Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.

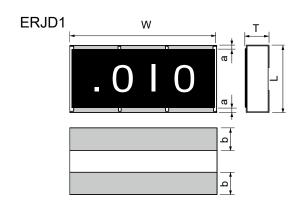


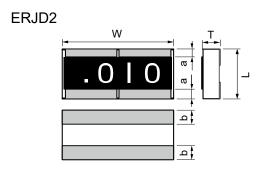
Low TCR High Power Chip Resistors (Wide Terminal Type)

Construction



Dimensions (not to scale)

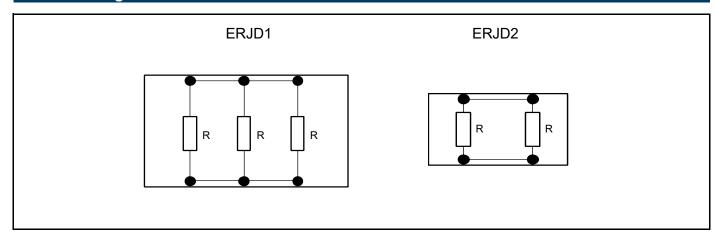




Unit : mm

Part No.	Dimensions								
Fait No.	L	W	а	b	Т	(g/1000 pcs)			
ERJD1	2.50±0.20	5.00±0.20	0.90±0.20	0.30±0.20	0.60±0.20	27			
ERJD2	1.60±0.15	3.20±0.20	0.50±0.20	0.30±0.20	0.65±0.15	11			

Circuit configuration



Low TCR High Power Chip Resistors (Wide Terminal Type)

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltag x 2.0, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



INDUSTRY



Anti-Surge Thick Film Chip Resistors

ERJ P, PA,PM type

ERJ PA2, P03, PA3, P06, P08, PM8, P14 series



Features

• ESD surge characteristics superior to standard metal film resistors

High reliability : Metal glaze thick film resistive element and three layers of electrodes

Suitable for both reflow and flow soldering

High power 0.20 W: 0603 inch / 1608 mm size (ERJP03)

0.20~W:0402~inch~/~1005~mm~size~(ERJPA2) 0.33~W:0603~inch~/~1608~mm~size~(ERJPA3)

0.50 W: 0805 inch / 2012 mm size (ERJP06), 1210 inch / 3225 mm size (ERJP14)

0.66 W: 1206 inch / 3216 mm size (ERJP08)

High precision, High voltage, High resistance value (ERJPM8)

: Limiting element voltage 500 V, Resistance tolerance ±1 %, TCR ±100 (x 10⁻⁶ / K)

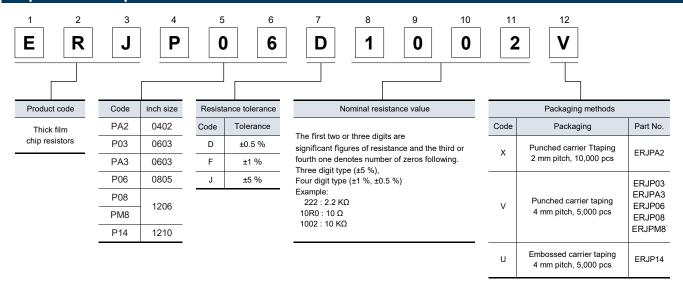
• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

AEC-Q200 compliant

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers



Anti-Surge Thick Film Chip Resistors

Ratings

Part No.		· -																				
ERJPA2 (0402)		rating*1	ambient temperature*2	terminal part temperature*2	element voltage ^{*3}	overload voltage ^{*4}	tolerance	range		temperature	Q200											
Company Comp	ERJPA2	0.20	70	-	50	100	±0.5, ±1		±100													
ERJP03 (0603) 0.20 70 - 150 200 \frac{\frig}}}{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac{\frac	(0402)	0.25	-	100	50	100	±5		±200		Grade 1											
(0603)			0.20 70	0.20 70	0.20 70	0.20 70	0.20 70				±0.5		±150									
ERJP06 (0805) 0.50 70 125 500 1000 ±1 1.02 100		0.20						-	150	200	±1		±200		ı							
ERJP08 (1206) 0.66 70 125 500 1000 ±1 1.02M to 10M (E24, E96) ±100 ±100 ERJP08 (1206) 0.66 70 125 500 1000 ±1 1.02M to 10M (E24, E96) ±100											1 to 1M	R<10Ω : –150 to +400										
ERJPA3 (0603) 0.33 - 130 200 ±5							±5	(E24)	10Ω≤R :±200													
Cool	ERJPA3		105	-	450	150 200			±100													
ERJP08 (1206) 0.50 70 115 400 600 100 115 400 600 100 115 400 600 100 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 115 400 600 600 115 400 600 600 115 400 600 600 600 600 600 600 600 600 600		0.33	-	130	150	200	±5		±200													
ERJP06 (0805) 0.50 70 115 400 600 ±5 1 to 3.3M (E24) 10Ω≤R<33Ω :±100 10Ω≤R<33Ω :±200 10Ω≤R<33Ω :±200 10Ω≤R<33Ω :±100 10Ω≤R<33Ω :±100 10Ω≤R<33Ω :±200 10Ω≤R<33Ω :±200 10Ω≤R<33Ω :±200 ±100 ±100 ±100 ERJPM8 (1206) 0.66 70 125 500 1000 ±1 1.02M to 10M (E24, E96) ±100 ±100 ERJPM8 (1206) ERJPM8 (1206) 0.50 70 - 200 400 ±0.5, ±1 10 to 1M (E24, E96) ±100 ±1																		.0.5 .4	10 to 1M	R<33Ω : ±300	−55 ~ +155	
(0805) 0.50 70 115 400 600 ±5 1 to 3.3M (E24) 10Ω≤R<33Ω : ±300 33Ω≤R : ±200 ERJP08 (1206) 0.66 70 125 500 1000 ±5 1 to 10M (E24, E96) 10Ω≤R : ±200 ERJPM8 (1206) 0.66 70 125 500 1000 ±1 1.02M to 10M (E24, E96) 10Ω≤R : ±200 ERJPM8 (1206) 0.50 70 - 200 400 ±5 1 to 11M (E24, E96) ±100 ERJP14 (1210) 0.50 70 - 200 400 ±5 1 to 11M (E24, E96) 10Ω≤R : ±100								ļ					±0.5, ±1	(E24, E96)	33Ω≤R :±100							
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		0.50	70	115	400	600			R<10Ω : -100 to +600		Grade 0											
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	(3333)						±5		10Ω≤R<33Ω :±300													
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$, ,	33Ω≤R :±200													
ERJPM8 (1206) 200 400 ±5 1 to 10M (E24) R<10Ω : -100 to +600 (E24) 10Ω≤R : ±200	ERJP08	0.00	70	405	500	1000	±0.5, ±1		±100													
ERJPM8 (1206) 0.66 70 125 500 1000 ±1 1.02M to 10M (E24, E96) ±100 ERJP14 (1210) 0.50 70 - 200 400 ±5 1 to 1M (E24, E96)	(1206)	0.00	70	125	500	1000		1 to 10M	R<10Ω : –100 to +600													
(1206) 0.66 70 125 500 1000 ±1 (E24, E96) ±100 ERJP14 (1210) 0.50 70 - 200 400 ±5 1 to 1M (E24, E96) ±100 (π) 1 to 1M (Ε24, Ε96) (Γ24)							ΞS	(E24)	10Ω≤R :±200													
ERJP14 (1210) 0.50 70 - 200 400 ±5 1 to 1M R<10Ω : -100 to +600		0.66	70	125	500	1000	±1		±100													
(1210) ±5 1 to 1M R<10Ω : -100 to +600	ERJP14	0.50	0.50 70 -	000	400	±0.5, ±1		±100														
	(1210)	0.50			200	400	+5	1 to 1M	R<10Ω : –100 to +600													
								(E24)	10Ω≤R :±200	1												

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

^{*2:} If there is a doubt whether the rated ambient temperature or the rated terminal part temperature is used, give priority to the

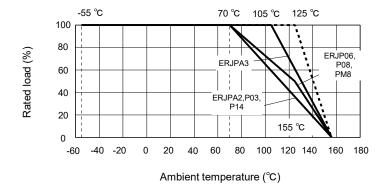
^{*3:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

^{*4:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Ratings

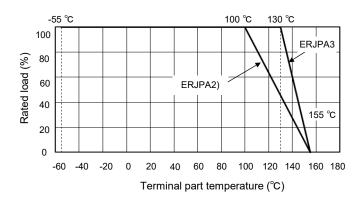
Power derating curve

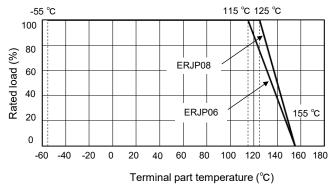
- •For resistors operated in ambient rated ambient temperature, power rating shall be derated in accordance with the figure below.
 - In addition, please use under the condition that the product temperature is below the upper category temperature.
 - % When the temperature of ERJP14 is 155 $^{\circ}$ C or less, the derating start temperature can be changed to 125 $^{\circ}$ C. (See the dotted line)



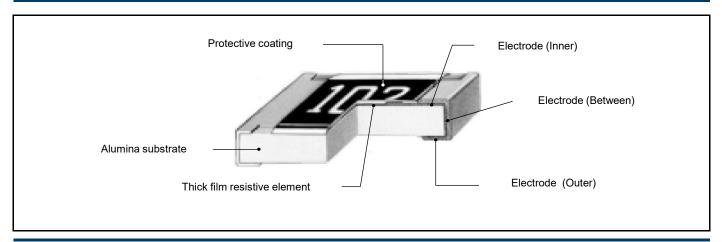
•For resistors operated in ambient rated terminal part temperature, power rating shall be derated in accordance with the figure below.

In addition, please use under the condition that the product temperature is below the upper category temperature.

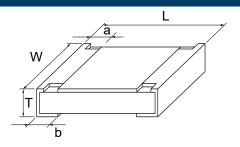




Construction



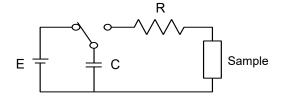
Dimensions (not to scale)



Unit : mm

Part No.	Dimensions									
	L	W	а	b	Т	(g/1000 pcs)				
ERJPA2	1.00±0.05	0.50±0.05	0.20±0.15	0.25±0.10	0.35±0.05	0.8				
ERJP03	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.30±0.15	0.45±0.10	2				
ERJPA3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2				
ERJP06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4				
ERJP08,PM8	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10				
ERJP14	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16				

ESD Characteristic



Size (inch)	0402	0603, 0805, 1206, 1210
R	1.5 kΩ	R=0 Ω(\leq 1.5 kΩ) / 150 Ω($>$ 1.5 kΩ)
С	100 pF	150 pF
Е	±1 kV	±3 kV

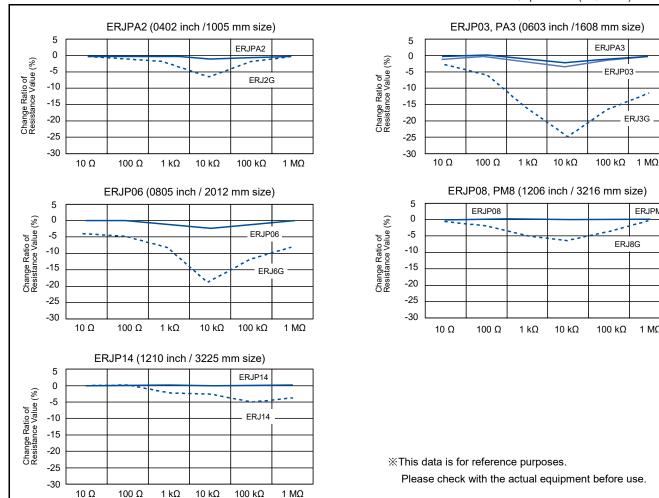
Anti-Surge Thick Film Chip Resistors (ERJP Series)

ERJ3G

ERJPM8

ERJ8G

Thick Film Chip Resistors (ERJ Series)



Anti-Surge Thick Film Chip Resistors

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃ (ERJPA2 : +125 ℃)
	±2 %	ERJP06 : Rated voltag× 1.77, 5 s
Overload	Only when it is ERJP03 (D),	ERJPA2, ERJPA3, ERJP08, ERJPM8: Rated voltag× 2.0, 5 s
	P14 (D) : ±0.5 %	ERJP03, ERJP14 : Rated voltag× 2.5, 5 s
Resistance to soldering heat	D: ±0.5 %, F, J: ±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30min.) / +155 ℃ (ERJPA2 : +125 ℃) (30min.), 1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity 1 (Applicable to rated ambient temperature-regulated products)	±3 % Only when it is ERJP03 (D), P14 (D) : ±1 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Load life in humidity 2 (Applicable to rated ambient temperature-regulated products)	±3 %	85 °C, 85 %RH, Rated power 10%, Continuously power, 1000 h
Durability at rated ambient temperature or rated terminal part temperature	±3 % Only when it is ERJP03 (D), P14 (D) : ±1 %	Rated ambient temperature or rated terminal part temperature, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

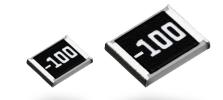
INDUSTRY

Anti-Pulse Thick Film Chip Resistors

ERJ T type

ERJ T06, T08, T14 series

ERJ T14L series



Features

- Anti-Pulse characteristics
 High pulse characteristics achieved by the optimized trimming specifications (ERJT06, T08, T14)
- Further high pulse characteristics achieved by trimming-less specifications (ERJT14L)
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power 0.25 W: 0805 inch /2012 mm size(ERJT06)

0.33 W: 1206 inch /3216 mm size(ERJT08)

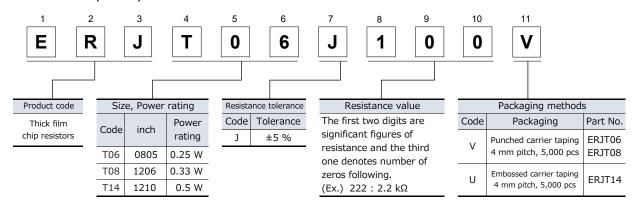
0.50 W: 1210 inch /3225 mm size(ERJT14, ERJT14L)

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

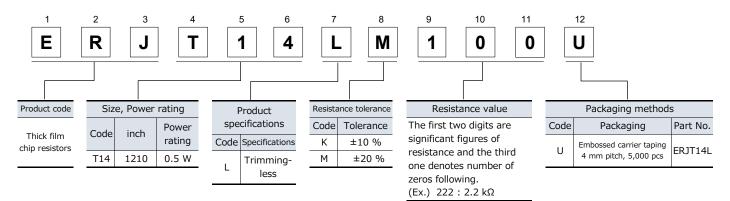
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

ERJT06, T08, T14 series



ERJT14L series



* Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

Anti-Pulse Thick Film Chip Resistors

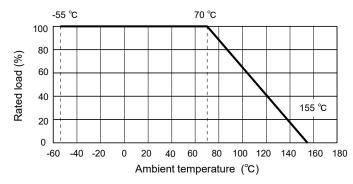
Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJT06 (0805)	0.25	150	200	±5	1 to 1 M (E24)	R<10 Ω : -100 to $+600$ 10 Ω≤R<33 Ω : ± 300 33 Ω≤R : ± 200		
ERJT08 (1206)	0.33	200	400	±5	1 to 1 M (E24)	R<10 Ω : -100 to +600 10 Ω≤R : ±200	–55 to +155	Grade 0
ERJT14 (1210)	0.50	200	400	±5	1 to 1 M (E24)	R<10 Ω : -100 to +600 10 Ω≤R : ±200		
ERJT14L (1210)	0.50	200	400	±10 ±20	1 to 1 M (E12)	R<10 Ω : -100 to +600 10 Ω≤R : ±200		

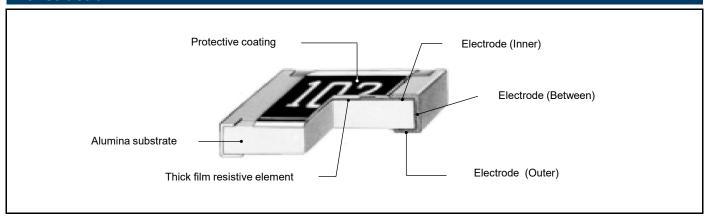
^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

Power derating curve

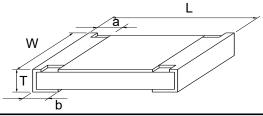
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions (not to scale)



Unit : mm

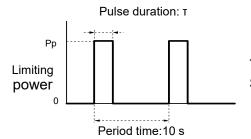
Part No.	Dimensions								
	L	W	а	b	Т	(g/1000 pcs)			
ERJT06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			
ERJT08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10			
ERJT14 ERJT14L	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16			

^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Limiting power curve

• In rush pulse Characteristic

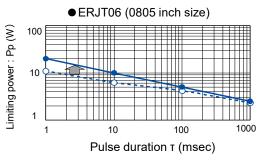


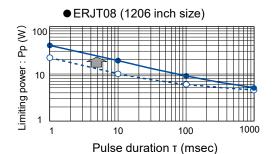
Test cycle: 1000 cycles

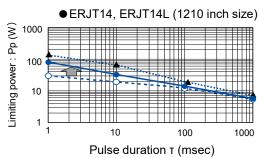
Spec : Resistance value = within ±5 %



 \bigcirc : Thick Film Chip Resistors(Series ERJ : 1 Ω)







- %This data is for reference purposes.
 Please check with the actual equipment before use.
- ※ Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃
Overload	±2 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃±3 ℃, 10 s ±1 s
Rapid change of temperature	±1 %	-55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃ ±2 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃ ±2 ℃, 90 % to 95 %RH, Rated voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70℃	±3 %	70 ℃ ±2 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors

ERJ S type (Au-based inner electrode type)

ERJ S02, S03, S06, S08, S14 series

ERJ S12, S1D, S1T series

ERJ U type (Ag-Pd-based inner electrode type)

ERJ U0X, U01, U02, U03, U06, U08, U14 series

ERJ U12. U1D. U1T. U6S. U6Q series

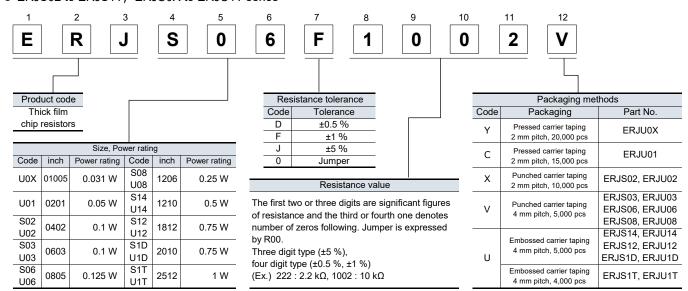


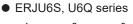
Features

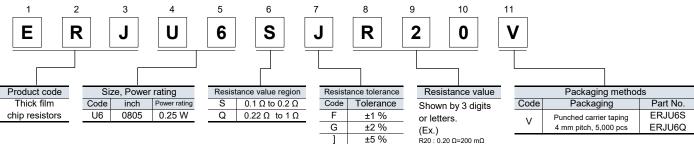
- High resistance to sulfurization achieved by adopting an Au-based inner electrode (Series ERJS) and Aq-Pd-based inner electrode (Series ERJU)
- : Metal glaze thick film resistive element and three layers of electrodes High reliability
- Suitable for both reflow and flow soldering
- : ERJU6S, U6Q series : 0.1 Ω to 1 Ω Low resistance type
- : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C Reference standard
- AEC-Q200 compliant (except ERJU0X, ERJU01)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

ERJS02 to ERJS1T, ERJU0X to ERJU1T series







Anti-Sulfurated Thick Film Chip Resistors

Rating	S								
Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJU0X				±1	10 to 1 M	(E24, E96)	R<10 Ω : –100 to +600		
(01005)	0.031	15	30	Ξ.		(LZ4, L30)	10 Ω≤R<100 Ω : ±300		
<u> </u>				±5	1 to 1 M	(E24)	100 Ω≤R :±200	-55 to +125	-
ERJU01	0.05	25	50	±1	10 to 1 M	(E24, E96)	R<10 Ω : –100 to +600		
(0201)	0.00	20	00	±5	1 to 1 M	(E24)			
ERJS02				±0.5, ±1	1 to 1 M	(E24, E96)	10 Ω to 1 MΩ : ±200		
ERJU02 (0402)	0.1	50	100	±5	1 to 3.3 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
ERJS03				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU03 (0603)	0.1	75	150	±5	1 to 10 M	(E24)			
ERJS06				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU06 (0805)	0.125	150	200	±5	1 to 10 M	(E24)			
ERJS08				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU08 (1206)	0.25	200	400	±5	1 to 10 M	(E24)	R<10 Ω : –100 to +600	551 .455	
ERJS14				±0.5, ±1	1 to 1 M	(E24, E96)	1 40 0 4 4 4 4 0 0 0 0 0 4 5 0 4 0	-55 to +155	Grade 0
ERJU14 (1210)	0.5	200	400	±5	1 to 10 M	(E24)	- 10 Ω to 1 MΩ : ±200 (± 5 %) : ±100 (±0.5 %, ±1 %)		
ERJS12				±0.5, ±1	1 to 1 M	(E24, E96)	(10.5 70, 11 70)		
ERJU12 (1812)	0.75	200	500	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
ERJS1D				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU1D (2010)	0.75	200	500	±5	1 to 10 M	(E24)			
ERJS1T				±0.5, ±1	1 to 1 M	(E24, E96)	-		
ERJU1T (2512)	1.0	200	500	±5	1 to 10 M	(E24)			

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

[Low resistance type]

Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Resistance tolerance (%)	Resistance range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJU6S (0805)	0.25	±1, ±2, ±5	0.1 to 0.2	(E24)	0 to +150	-55 to +155	Grade 0
ERJU6Q (0805)	0.25	± 1, ±2, ±3	0.22 to 1	(E24)	0 10 +150	-55 10 + 155	Grade 0

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

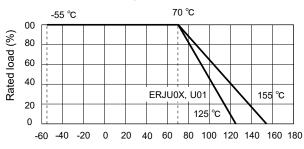
[For jumper]

ti oi juilibeij			
Part No.	Resistance	Rated current	Maximum overload current ^{*1}
ERJU0X		0.5 A	1 A
ERJU01		0.5 A	1.7
ERJS02,ERJU02		1 A	2 A
ERJS03,ERJU03		1.4	2 A
ERJS06,ERJU06	100 mΩ or less		
ERJS08,ERJU06	100 11122 01 1655		
ERJS14,ERJU14		2 A	4 A
ERJS12,ERJU12		27	7.7
ERJS1D,ERJU1D			
ERJS1T,ERJU1T			

^{*1:} Overload test current

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



Ambient temperature (°C)

^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

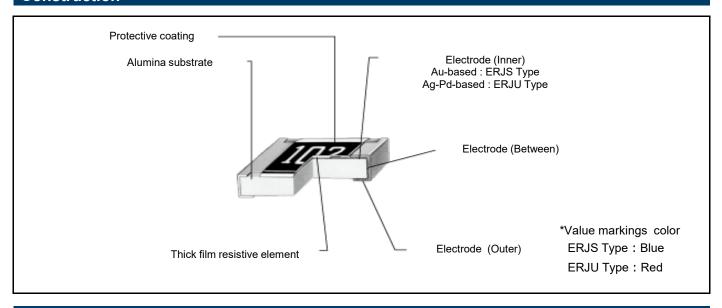
^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

[•] Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(Power Rating \times Resistance Value. \)

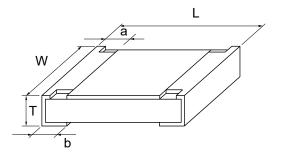
[·] Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Anti-Sulfurated Thick Film Chip Resistors

Construction



Dimensions (not to scale)



Unit: mm

Part No.	Dimensions								
Part No.	L	W	а	b	Т	(g/1000 pcs)			
ERJU0X	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04			
ERJU01	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15			
ERJS02 ERJU02	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8			
ERJS03 ERJU03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJS06 ERJU06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4			
ERJU6□	2.00±0.20	1.25±0.10	0.45±0.20	0.45±0.20	0.55±0.10	6			
ERJS08 ERJU08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
ERJS14 ERJU14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
ERJS12 ERJU12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27			
ERJS1D ERJU1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27			
ERJS1T ERJU1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			

Anti-Sulfurated Thick Film Chip Resistors

Performance

• ERJS02 to ERJS1T, ERJU0X to ERJU1T series

Test item	Performance re	quirements ⊿R	Test conditions
Test item	Resistor type	Jumper type	rest conditions
Resistance	Within specified tolerance	100 mΩ or less	20 ℃
T. C. R.	Within Specified T. C. R.	200 mΩ or less	+25 ℃ / +155 ℃ (ERJU0X,U01 : +25 ℃ / +125 ℃)
Overload	±2 %	100 mΩ or less	Rated voltage × 2.5, 5 s Jumper type : Max. overload current, 5 s
Resistance to soldering heat	±1 %	100 mΩ or less	270 ℃, 10 s
Rapid change of temperature	±1 %	100 mΩ or less	–55 ℃ (30min.)/+155 ℃ (ERJU0X,U01 : +125 ℃) (30min.), 100 cycles
High temperature exposure	±1 %	100 mΩ or less	+155 ℃ (ERJU0X,U01 : +125 ℃), 1000 h
Damp heat, Steady state	±1 %	100 mΩ or less	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	100 mΩ or less	60 ℃, 90 % to 95 %RH, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	100 mΩ or less	70 ℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h

• ERJU6S, U6Q series

Ertodo, dog sene	_	
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±1 %	Rated voltage × 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	-55 ℃ (30 min.) / +125 ℃ (30min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors (Precision Type)



ERJ U□R type (Ag-Pd-based inner electrode type)

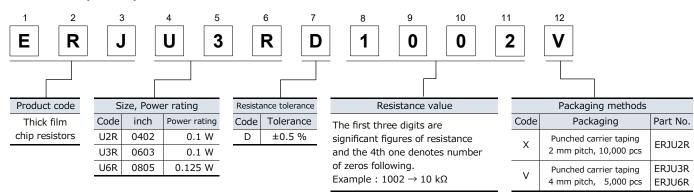
ERJ U2R, U3R, U6R series

Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode.
- High precision : Resistance tolerance : $\pm 0.5 \%$, TCR : $\pm 50 \times 10^{-6}$ /K
- High reliability : Metal glaze thick film resistive element and three layers of electrodes.
- Suitable for both reflow and flow soldering.
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

ERJU2R, U3R, U6R series



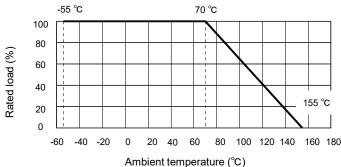
Ratings

Part No. (inch size)	Power rating*1 (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJU2R (0402)	0.1	50	100	±0.5	100 to 100 k (E24, E96)			
ERJU3R (0603)	0.1	75	150	±0.5	100 to 100 k (E24, E96)	±50	-55 to +155	Grade 0
ERJU6R (0805)	0.125	150	200	±0.5	100 to 100 k (E24, E96)			<u> </u>

- *1 : Use it on the condition that the case temperature is below the upper category temperature.
- *2 : Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or limiting element voltage listed above, whichever less.
- *3 : Overload test voltage (OTV) shall be determined from OTV = Specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

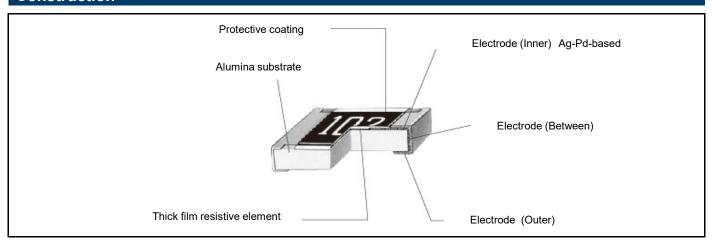
Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.

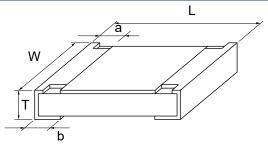


Anti-Sulfurated Thick Film Chip Resistors (Precsion Type)

Construction



Dimensions (not to scale)



Unit : mm

Part No.	Dimensions							
Fait No.	L	W	а	b	Т	(g/1000 pcs)		
ERJU2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	8.0		
ERJU3R	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2		
ERJU6R	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4		

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃
Overload	±2 %	Rated voltage × 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±2 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±2 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)

ERJ UP type

ERJ UP3, UP6, UP8 series



Features

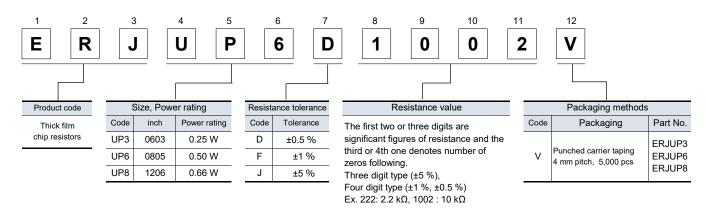
- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure
- ESD surge characteristics superior to standard metal film resistors
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power 0.25 W: 0603 inch / 1608 mm size (ERJUP3)

0.50 W: 0805 inch / 2012 mm size (ERJUP6) 0.66 W: 1206 inch / 3216 mm size (ERJUP8)

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers



Ratings

Part No. (inch size)	Power rating*1 (70 ℃) (W)	Limiting element voltage*2 (V)	Maximum overload voltage*3 (V)	Resistance tolerance (%)	rar	stance nge Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (°C)	AEC-Q200 Grade
ERJUP3	0.25	150 200	200	±0.5, ±1	10 to 1 M	(E24, E96)	±100		
(0603)	0.23			200	200	±5	1 to 1.5 M	(E24)	±200
ED 11.100				±0.5, ±1	10 to 1 M	(E24, E96)	±100		
ERJUP6 (0805)	0.50	400	600	±5	1 to 3.3 M	1 (E24)	R<10 Ω : –100 to +600	-55 to +155	Grade 0
(0000)				10	1 10 3.3 W	(E24)	10 Ω≤R :±200	-55 10 +155	Grade 0
ED 11 100	ERJUP8 0.66 50			±0.5, ±1	10 to 1 M	(E24, E96)	±100		
(1206)		500	1000		1 to 10 M	(E24)	R<10 Ω : –100 to +600		
(1200)			±5	1 to 10 M	(E24)	10 Ω≤R :±200			

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

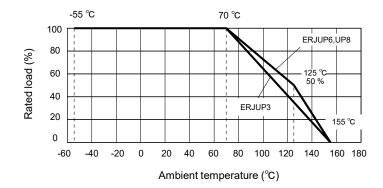
^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)

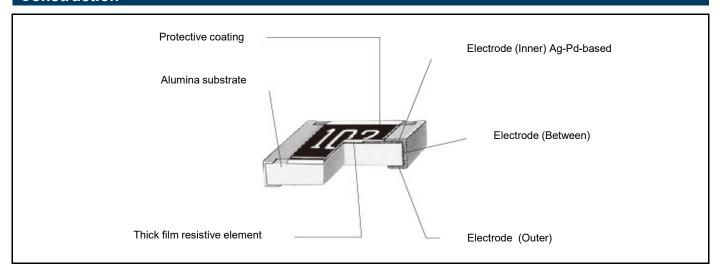
Ratings

Power derating curve

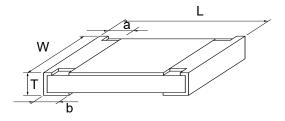
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions in mm (not to scale)

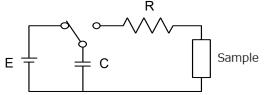


Unit : mm

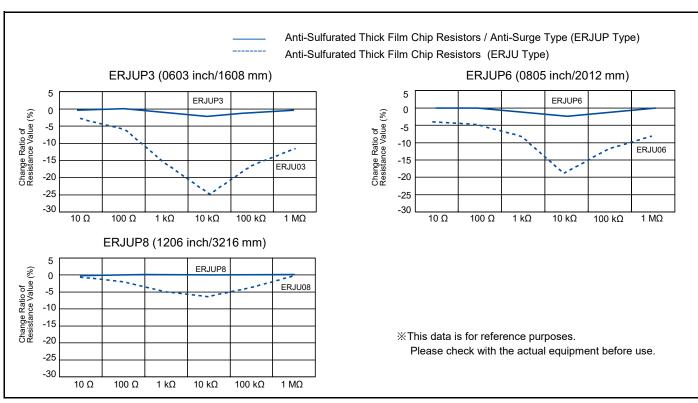
Part No.	Dimensions								
	L W a b T								
ERJUP3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2			
ERJUP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			
ERJUP8	3.20+0.05/-0.20	1.6+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10			

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)

ESD Characteristic



R	R=0 Ω(\leq 1.5 kΩ) / 150 Ω($>$ 1.5 kΩ)
С	150 pF
E	±3 kV



Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃
Overland	12.0/	ERJUP6: Rated voltag x 1.77, 5 s
Overload	±2 %	ERJUP3, ERJUP8: Rated voltag x 2.0, 5 s
Resistance to soldering heat	D: ±0.5 % F, J: ±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	-55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY





ERJ C type
ERJ C1 series

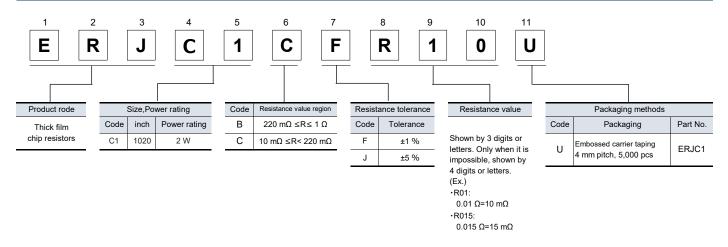
Features

- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure (Covered electrode)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended applications

- Motor control circuit of the industrial equipment
- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers



Ratings

Part No. (inch size)	Power rating ^{*1} (70 °C) (W)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJC1 (1020)	2	±1	10 m to 1 (E24)	$10 \text{ m}\Omega \leq R < 22 \text{ m}\Omega : 0 \text{ to } +350$ $22 \text{ m}\Omega \leq R < 47 \text{ m}\Omega : 0 \text{ to } +200$ $47 \text{ m}\Omega \leq R < 100 \text{ m}\Omega : 0 \text{ to } +150$ $100 \text{ m}\Omega \leq R \leq 1 \Omega : \pm 100$	-55 to +155	Grade 0
		±5		$10 \text{ m}\Omega \le R < 22 \text{ m}\Omega : 0 \text{ to } +350$ $22 \text{ m}\Omega \le R < 100 \text{ m}\Omega : 0 \text{ to } +200$ $100 \text{ m}\Omega \le R \le 1 \Omega : \pm 200$		

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

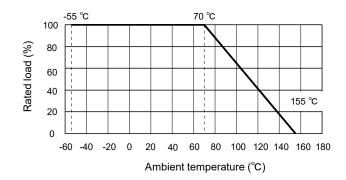
- Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating × Resistance Value.
- · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)

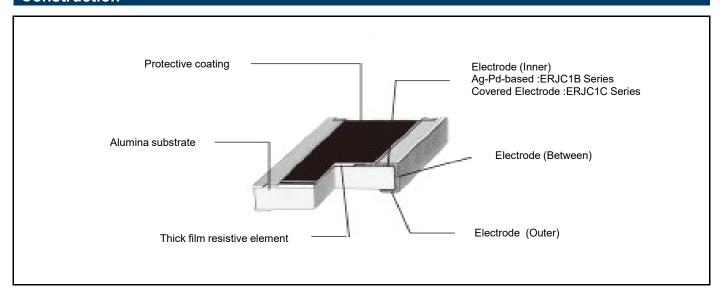
Ratings

Power derating curve

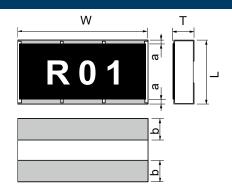
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions (not to scale)

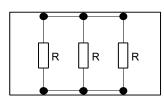


Unit : mm

Part No	Dimensions								
	L	W	а	b	Т	(g/1000 pcs)			
ERJC1B	2.50±0.20	5.00±0.20	0.35±0.20	0.90±0.20	0.55±0.20	27			
ERJC1C 2.50±0.20		5.00±0.20	0.60±0.20	0.90±0.20	0.55±0.20				

Circuit configuration

ERJC1 series



Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)

60 °C, 90 % to 95 %RH, 1000 h

60 ℃, 90 % to 95 %RH, Rated voltage,

1.5 h ON / 0.5 h OFF cycle, 1000 h

70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Performance Performance Test Item Test conditions requirements ⊿R Within specified Resistance 20 ℃ tolerance Within specified T. C. R. +25 ℃ / +125 ℃ T. C. R. Overload ±2 % Rated voltage × 2.0, 5 s Resistance to ±1 % 270 ℃, 10 s soldering heat Rapid change of ±2 % -55 °C (30 min.) / +125 °C (30 min.), 1000 cycles temperature High temperature +155 ℃, 1000 h ±1 % exposure Damp heat,

±1 %

±3 %

±3 %

Steady state

Load life in humidity

Endurance at 70 ℃

INDUSTRY

High Temperature Thick Film Chip Resistor (Automotive Grade)



ERJH type

ERJ H2G, H2C, H2R, H3G series

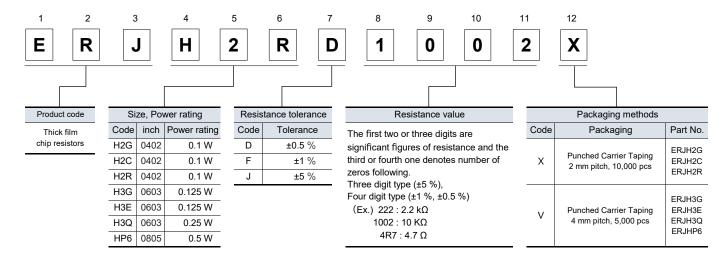
ERJ H3E, H3Q, H6G, HP6 series

Features

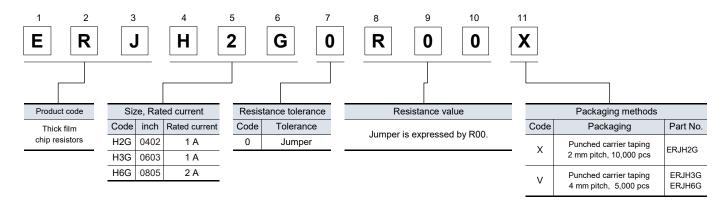
- High reliability : Metal glaze thick film resistive element and high temperature of electrodes structure
- Achieve maximum category temperature 175 ℃ and rated category temperature 105 ℃
- Compatible with placement machines : Taping packaging available
- Suitable for both reflow and flow soldering
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

• ERJH2G, H2C, H2R, H3G, H3E, H3Q, HP6 series: ±0.5 %, ±1 %, ±5 %



• ERJH2G, H3G, H6G series : Jumper



High Temperature Thick Film Chip Resistor (Automotive Grade)

Ratings

[For Resistor]

Part No. (inch size)	Power rating*1 (105 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (°C)	AEC-Q200 Grade
ERJH2G (0402)	0.1	50	100	±5	1 to 300 k	(E24)	R < 10Ω : -100 to +600 10Ω ≤ R : ± 200		
ERJH2C (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600		
ERJH2R (0402)	0.1	50	100	±0.5,±1	10 to 300 k	(E24,E96)	±100		
ERJH3G (0603)	0.125	75	150	±5	1 to 300 k	10Ω ≤ R : ± 200		554 475	Crado 0
ERJH3E (0603)	0.125	75	150	±0.5,±1	10 to 300 k				
ERJH3Q	0.25	_	_	±0.5,±1	1 to 9.76	(E24,E96)	±200	-55 to +175	Grade 0
(0603)	0.20			±5	1 to 9.1	(E24)			
	0.5	400	600	±0.5	10 to 300 k	(E24,E96)	R < 33Ω : ±300		
	0.0		000			(== :,===)	$33\Omega \leq R: \pm 100$		
							$R < 10\Omega : -100 \text{ to } +600$		
ERJHP6	0.5	400	600	±1	1 to 300 k	(E24,E96)	$10\Omega \le R < 33\Omega : \pm 300$		
(0805)							$33\Omega \leq R: \pm 100$		
		400 600		±5			$R < 10\Omega : -100 \text{ to } +600$		
	0.5		600		1 to 300 k	(E24)	10Ω ≤R < 33Ω : ±300		
							$33\Omega \leq R : \pm 100$		

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

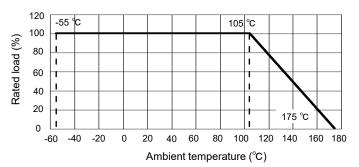
[For Jumper]

Part No. (inch size)	Resistance	Rated current	Maximum overload current*1		
ERJH2G (0402)	50 mΩ or less	1 A			
ERJH3G (0603)		1 A	2 A		
ERJH6G (0805)		2 A	4 A		

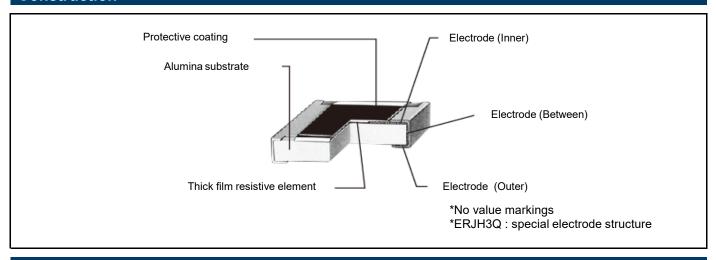
^{*1:} Overload test current

Power derating curve

For resistors operated in ambient temperatures above 105 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



Construction

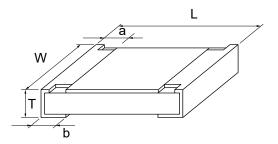


^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

High Temperature Thick Film Chip Resistor (Automotive Grade)

Dimensions (not to scale)



Unit : mm

Part No.		Dimensions									
Part NO.	L	W	а	b	Т	(g/1000 pcs)					
ERJH2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8					
ERJH2C	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8					
ERJH2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	8.0					
ERJH3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2					
ERJH3E	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2					
ERJH3Q	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2					
ERJH6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4					
ERJHP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4					

Test item	Performance re	equirements ⊿R	Test conditions
restitem	Resistor type	Jumper type	rest conditions
Resistance	Within specified tolerance	50 mΩ or less	20 ℃
T. C. R.	Within specified T. C. R.	50 mΩ or less	+25 °C / +175 °C
Overload	±2 %	50 mΩ or less	ERJH2G, H2C, H2R, H3G, H3E, H3Q : Rated voltage× 2.5, 5 s ERJHP6: Rated voltage× 1.77, 5 s Jumper type: Max. overload current, 5 s
Resistance to soldering heat	±1 %	50 mΩ or less	270 ℃, 10 s
Rapid change of temperature	±1 %	50 mΩ or less	–55 °C (30 min.) / +175 °C (30 min.), 1000 cycles
High temperature exposure	±1 %	50 mΩ or less	+175 ℃, 1000 h
Damp heat, Steady state	±1 %	50 mΩ or less	85 ℃, 85 %RH, 1000 h
Load life in humidity	±3 %	50 mΩ or less	85 °C, 85 %RH, Rated voltage (Jumper type :Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 105 ℃	±3 %	50 mΩ or less	105 ℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Chip Resistors Array

EXB type

EXB 14V, 18V, 24V, 28V, N8V, 2HV, series

EXB 34V, V4V, 38V, V8V, S8V series



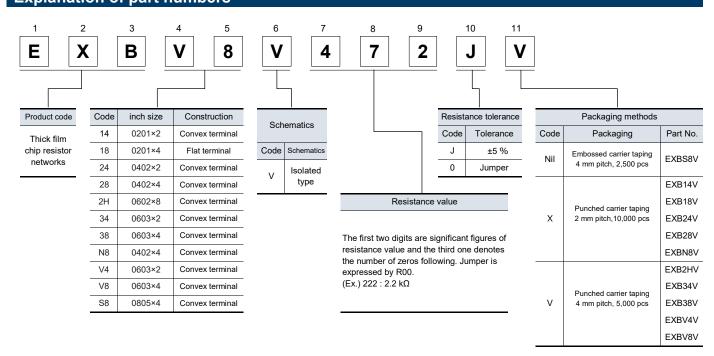
Features

- High density
 - 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size : EXB14V
 - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXB18V
 - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXB24V
 - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXB28V, N8V
 - 8 resistors in 3.8 mm × 1.6 mm size / 1506 inch size : EXB2HV
 - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXB34V, V4V
 - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXB38V, V8V
 - 4 resistors in 5.1 mm × 2.2 mm size / 2009 inch size : EXBS8V
- Improvement of placement efficiency

Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor

- : IEC 60115-9, JIS C 5201-9, EIAJ RC-2129 Reference Standard
- AEC-Q200 compliant (EXB2, EXB3)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers



Ratings

[For Resistor]

Part No. (inch size)	Power rating (70 ℃) (W/element)	Limiting element voltage ^{*1} (V)	Maximum overload voltage ^{*2} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (°C)	AEC-Q200 Grade
EXB14V (0201×2)	0.031	12.5	25	±5	10 to 1 M (E24)			
EXB18V (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M (E24)			-
EXB24V (0402×2)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	
EXB28V (0402×4)	0.063	50	100	±5	1 to 1 M (E24)			
EXB2HV (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M (E24)	R<10 Ω		Grade 1
EXB34V (0603×2)	0.063	50	100	±5	1 to 1 M (E24)	: -200 ~ +600 10 Ω ~ 1 MΩ		
EXB38V (0603×4)	0.063	50	100	±5	1 to 1 M (E24)	: ±200		
EXBN8V (0402×4)	0.031	50	100	±5	10 to 1 M (E24)			
EXBV4V (0603×2)	0.063	50	100	±5	10 to 1 M (E24)			
EXBV8V (0603×4)	0.063	50	100	±5	10 to 1 M (E24)			-
EXBS8V (0805×4)	0.1	100	200	±5	10 to 1 M (E24)			

^{*1:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

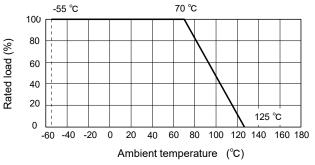
[For Jumper]

Part No.	Resistance	Rated current	Maximum overload current ^{*1}
EXB14V		0.5 A	1 A
EXB18V		0.5 A	1 A
EXB24V		1 A	2 A
EXB28V		1 A	2 A
EXB2HV		1 A	2 A
EXB34V	50 mΩ or less	1 A	2 A
EXB38V		1 A	2 A
EXBN8V		1 A	2 A
EXBV4V		1 A	2 A
EXBV8V		1 A	2 A
EXBS8V		2 A	4 A

^{*1:} Overload test current

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.

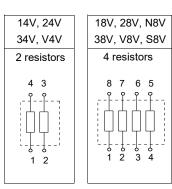


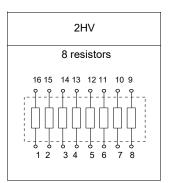
Construction (Example : Concave terminal)

Protective coating Alumina substrate Electrode (Outer) Thick film Electrode (Between) resistive element Electrode (Inner)

Schematics

● Isolated type



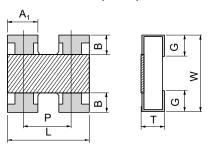


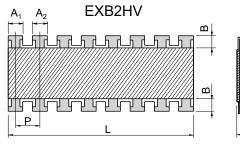
^{*2:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Dimensions (not to scale)

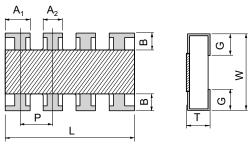
(1) Convex terminal type

EXB14V, 24V, 34V









Unit:mm

Part No.				Dime	nsions				Mass (Weight)
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)
EXB14V (0603X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5
EXB24V (1005×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2
EXB28V (1005×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0
EXB2HV (1605×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0
EXB34V (1608×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5
EXB38V (1608×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0

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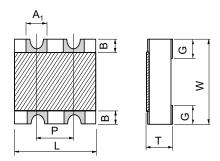
Т

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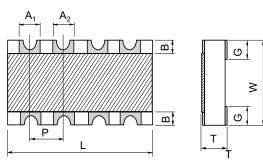
() Reference

(2) Concave terminal type

EXBV4V



EXBN8V, V8V, S8V



Unit : mm

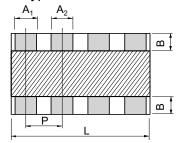
Part No.	Dimensions								
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)
EXBN8V (1005×4)	2.00±0.10	1.00±0.10	0.45±0.10	0.30±0.10	0.30±0.10	0.20±0.15	(0.50)	0.30±0.15	3.0
EXBV4V (1608×2)	1.60 +0.20/-0.10	1.60 +0.20/-0.10	0.60±0.10	0.60±0.10	_	0.30±0.15	(0.80)	0.45±0.15	5.0
EXBV8V (1608×4)	3.20 +0.20/-0.10	1.60 +0.20/-0.10	0.60±0.10	0.60±0.10	0.60±0.10	0.30±0.15	(0.80)	0.45±0.15	10
EXBS8V (2012×4)	5.08 +0.20/-0.10	2.20 +0.20/-0.10	0.70±0.20	0.80±0.15	0.80±0.15	0.50±0.15	(1.27)	0.55±0.15	30

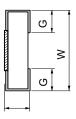
() Reference

Dimensions (not to scale)

(3) Flat terminal type

EXB18V





Unit : mm

Part No.	Dimensions									
(inch size)	L	W	Т	A ₁	A_2	В	Р	G	(g/1000 pcs)	
EXB18V (0603×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0	

() Reference

Test Item	Performance	Test conditions
restitem	requirements ⊿R	rest containons
	Within specified	
Resistance	tolerance	20 ℃
T. C. R.	Within specified	+25 ℃ / +125 ℃
1. 0. 1.	T. C. R.	123 67 1123 6
Overload	±2 %	Rated voltage x 2.5, 5 s
Overload	±2 %	Jumper type : Max. overload current, 5 s
Resistance to	4.07	272.00.42
soldering heat	±1 %	270 ℃, 10 s
Rapid change of	. 4.0/	10 (co.)
temperature	±1 %	-55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature	14.0/	.405 °C .4000 b
exposure	±1 %	+125 ℃, 1000 h
Damp heat,	.4.0/	00 °C 00 0/ 1 05 0/ DU 4000 I
Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
		60 ℃, 90 % to 95 %RH, Rated voltage
Load life in humidity	±3 %	(Jumper type : Rated current),
•		1.5 h ON / 0.5 h OFF cycle, 1000 h
	2.0/	70 ℃, Rated voltage (Jumper type :Rated current),
Endurance at 70 ℃	±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h

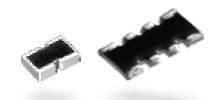
INDUSTRY

Anti-Sulfurated Chip Resistors Array

EXB type

EXB 14V, 18V, 24V, 28V, N8V, 2HV series

EXB 34V, V4V, 38V, V8V, S8V series



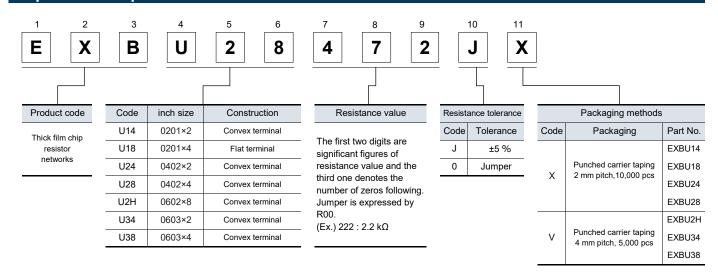
Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode
- High density
 - 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size : EXBU14
 - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXBU18
 - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXBU24
 - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXBU28
 - 8 resistors in 3.8 mm × 1.6 mm size / 1506 inch size : EXBU2H
 - o resistors in 3.0 min * 1.0 min size / 1500 inch size . EXDUZE
 - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXBU34 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXBU38
- Improvement of placement efficiency

Placement efficiency of chip resistor array is two, four or eight times of the flat type chip resistor

- Reference standard : IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 compliant (EXBU2, EXBU3)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers



Ratings

[For Resistor]

Part No. (inch size)	Power rating (70 ℃) (W/element)	Limiting element voltage ^{*1} (V)	Maximum overload voltage ^{*2} (V)	Resistance tolerance (%)	Resistance range (Ω)		range		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (°C)	AEC-Q200 Grade
EXBU14 (0201×2)	0.031	12.5	25	±5	10 to 1 M	(E24)					
EXBU18 (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M	(E24)		-55 to +125	-		
EXBU24 (0402×2)	0.063	50	100	±5	1 to 1 M	(E24)	11 10 11				
EXBU28 (0402×4)	0.063	50	100	±5	1 to 1 M	(E24)	: –200 to +600 10 Ω to 1 MΩ				
EXBU2H (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M	(E24)	: ±200		Grade 1		
EXBU34 (0603×2)	0.063	50	100	±5	1 to 1 M	(E24))				
EXBU38 (0603×4)	0.063	50	100	±5	1 to 1 M	(E24)					

^{*1:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

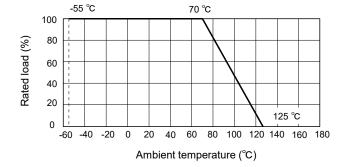
[For Jumper]

Part No.	Resistance	Rated current	Maximum overload current ^{*1}
EXBU24			
EXBU28			
EXBU2H	100 mΩ or less	1 A	2 A
EXBU34			
EXBU38			

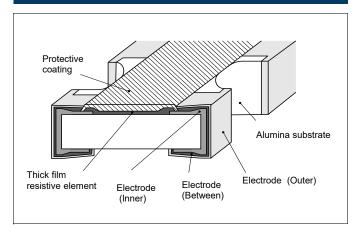
^{*1:} Overload test current

Power derating curve

For resistors operated in ambient temperatures above 70℃, power rating shall be derated in accordance with the figure below.

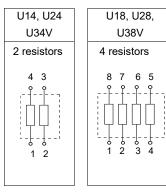


Construction



Schematics

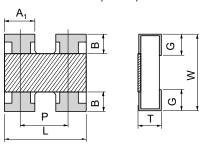
● Isolated type



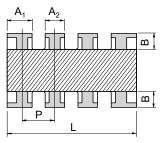
^{*2:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

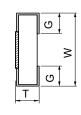
Dimensions (not to scale)

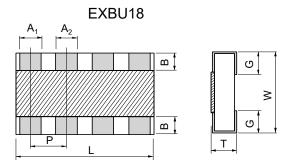
EXBU14, U24, U34

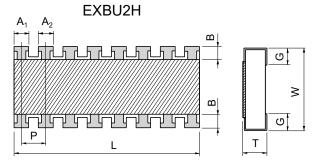












Unit : mm

Part No.	Dimensions								
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)
EXBU14 (0201X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5
EXBU18 (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0
EXBU24 (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2
EXBU28 (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0
EXBU2H (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0
EXBU34 (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5
EXBU38 (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0

() Reference

Periormance						
Test Item	Performance	Test conditions				
rest item	requirements ⊿R	1651 CONDITIONS				
Resistance	Within specified	20 ℃				
	tolerance	20 0				
T. C. R.	Within Specified	+25 ℃ / +125 ℃				
	T. C. R.					
Overload	±2 %	Rated voltage x 2.5, 5 s				
	/*	Jumper type : Max. overload current, 5 s				
Resistance to	±1 %	270 ℃, 10 s				
soldering heat		, -				
Rapid change of	±1 %	$-55 ^{\circ}\text{C} (30 \text{min.}) / +125 ^{\circ}\text{C} (30 \text{min.}), 100 \text{cycles}$				
temperature						
High temperature	±1 %	+125 ℃, 1000 h				
exposure Domp boot						
Damp heat,	±1 %	60 ℃, 90 % to 95 %RH, 1000 h				
Steady state		60 °C 00 0/ to 05 0/ DLL Detect voltage				
Load life in humidity	±3 %	60 °C, 90 % to 95 %RH, Rated voltage				
Load life in humidity		(Jumper type : Rated current),				
		1.5 h ON / 0.5 h OFF cycle, 1000 h				
Endurance at 70℃	±3 %	70℃, Rated voltage (Jumper type : Rated current),				
		1.5 h ON / 0.5 h OFF cycle, 1000 h				

INDUSTRY

Chip Resistors Networks

EXB type

EXB D, E, A, Q series



Features

- High density placing for digital signal circuits
 - ·Bussed 8 or 15 resistors for pull up/down circuits

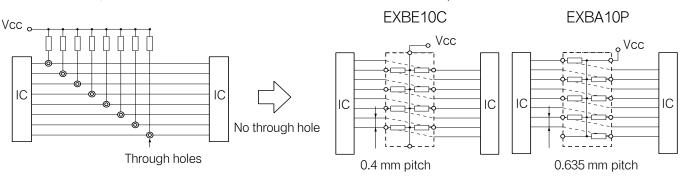
EXBD : $3.2 \text{ mm} \times 1.6 \text{ mm} \times 0.55 \text{ mm}$, 0.635 mm pitch EXBE : $4.0 \text{ mm} \times 2.1 \text{ mm} \times 0.55 \text{ mm}$, 0.8 mm pitch EXBA : $6.4 \text{ mm} \times 3.1 \text{ mm} \times 0.55 \text{ mm}$, 1.27 mm pitch EXBQ : $3.8 \text{ mm} \times 1.6 \text{ mm} \times 0.45 \text{ mm}$, 0.5 mm pitch

- Available direct placing on the bus line by means of half pitch spacing without through-holes on PWB ("High density placing" is shown below)
- High speed mounting using conventional placing machine
- Reference Standard : IEC 60115-9, JIS C 5201-9, EIAJ RC-2130
- RoHS compliant

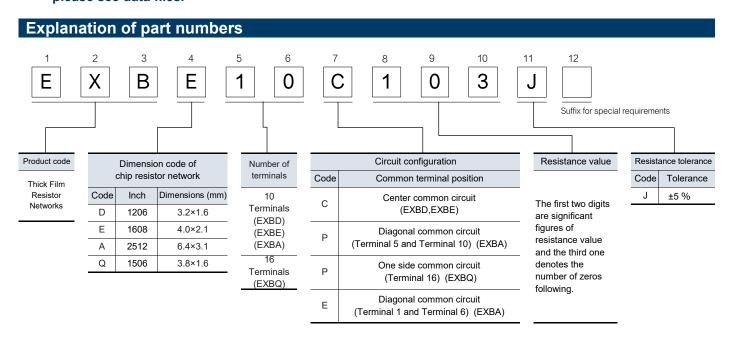
[High density placing]

Pull up resistors

Direct placement on the bus line



■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.



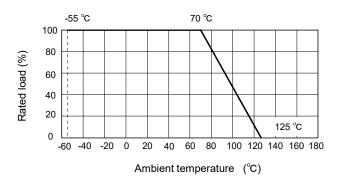
Ratings

Part No. (inch size)	Resistance range (Ω)	Resistance tolerance (%)	Number of terminals	Number of resistors	Power rating ^{*1} (70 °C) (W/element)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
EXBD (1206)		±5	10 terminals	8 element	0.05 / element	25	50	±200	55 to +125	-
EXBE (1608)	47 to 1 M (E12)				0.063 / element	25	50	±200		
EXBA (2512)					0.063 / element	50	100	±200		
EXBQ (1506)	100 to 470 k (E6)		16 terminals	15 element	0.025 / element	25	50	±200		

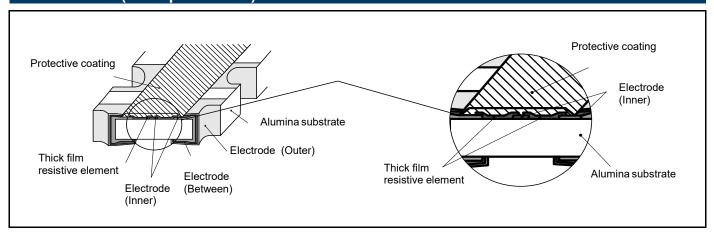
^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

Power derating curve

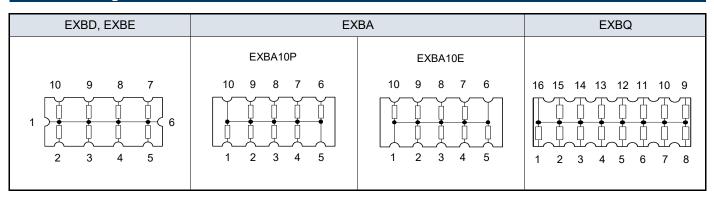
For resistors operated in ambient temperatures above 70 ℃, power rating shall be derated in accordance with the figure on the right.



Construction (Example: EXBD)



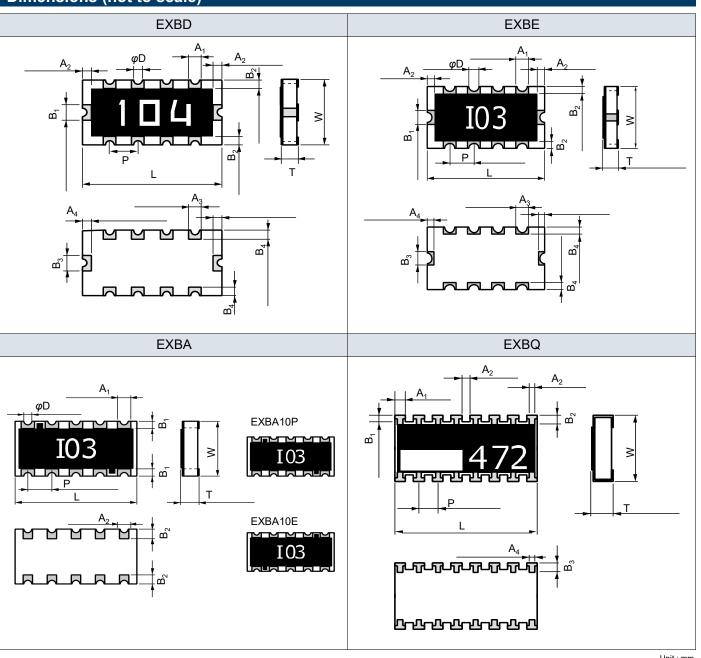
Circuit configuration



^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Dimensions (not to scale)



								Unit : mm		
Part No.	Dimensions									
i ait ivo.	L	W	T	A ₁	A_2	B ₁	B ₂	(g/1000 pcs)		
	3.20±0.15	1.60±0.15	0.55±0.10	0.33±0.15	0.2±0.1	0.40±0.15	0.2±0.1	10		
EXBD	A_3	A_4	B ₃	B ₄	Р	ø D				
	0.3±0.1	0.25±0.10	0.40±0.15	0.35±0.15	0.635±0.10	0.2±0.1				
D 111				Dimensions				Mass (Weight)		
Part No.	L	W	T	A ₁	A_2	B ₁	B ₂	(g/1000 pcs)		
	4.0±0.2	2.1±0.2	0.55±0.10	0.5±0.2	0.3±0.2	0.5±0.2	0.25±0.20	16		
EXBE	A_3	A_4	B_3	B ₄	Р	ø D				
	0.4±0.2	0.35±0.20	0.5±0.2	0.4±0.2	0.8±0.1	0.3+0.1/-0.2				
Part No.	Dimensions							Mass (Weight)		
Part No.	L	W	Т	A ₁	B ₁	A ₂	B ₂	(g/1000 pcs)		
	6.4±0.2	3.1±0.2	0.55±0.10	0.7±0.2	0.3±0.2	0.5±0.2	0.5±0.20	40		
EXBA	Р	ø D								
	1.27±0.10	0.3+0.1/-0.2								
Don't No	Dimensions									
Part No.	L	W	Т	A ₁	A ₂	A_3	B ₁	(g/1000 pcs)		
		16102	0.45±0.10	0.3±0.1	0.2±0.1	0.15+0.15/-0.05	0.15+0.15/-0.05			
	3.8±0.2	1.6±0.2	0.40±0.10							
EXBQ	3.8±0.2 B ₂	A ₄	B ₃	Р				9		

Chip Resistors Networks

Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±3 %	Rated voltage x 2.5, 5 s
Resistance to soldering heat	±1 %	260 ℃ ±5 ℃, 5 s ±1 s
Rapid change of temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 5 cycles
High temperature exposure	±3 %	+125 ℃, 100 h
Load life in humidity	±3 %	60 ℃±2 ℃, 90 % to 95 %RH, Rated power × 0.1, 1.5 h ON / 0.5 h OFF cycle, 500 h
Endurance at 70 ℃	±5 %	70 ℃±2 ℃,Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

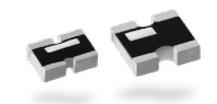
Panasonic

INDUSTRY

Chip Attenuator

EXB type

EXB 14AT, 24AT series



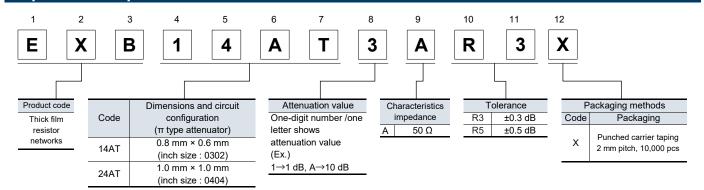
Features

- Unbalanced π type attenuator circuit in one chip EXB14AT (0.8 mm×0.6 mm), EXB24AT (1.0 mm×1.0 mm)
- Reduced mounting area
 - EXB14AT : About 60 % smaller than the area of an attenuator circuit consisting of three 0603 chip resistors, almost equal to the area of three 0402 chip resistors
 - EXB24AT : About 50 % smaller than the area of an attenuator circuit consisting of three 1005 chip resistors, almost equal to the area of three 0603 chip resistors
- Mounting cost reduction: (Only 1 chip placed as compared to 3)
- Attenuation: 1 dB to 10 dB
- RoHS compliant

Recommended applications

- Attenuation / level control / impedance matching of high frequency (communication signalling equipment cellular phones(GSM, CDMA, PDC, etc.), PHS, PDAs)
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

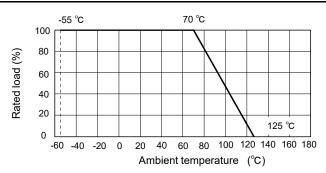


Ratings	
Part No.	EXB14AT, EXB24AT
Attenuation value	1 dB, 2 dB, 3 dB, 4 dB, 5 dB, 6 dB, 10 dB*
Attenuation value tolerance	1 dB, 2 dB, 3 dB, 4 dB, 5dB: ±0.3 dB
Attenuation value tolerance	6 dB, 10 dB: ±0.5 dB
Characteristic impedance	50 Ω
Power rating at 70 ℃	0.04 W / package
Frequency range	DC to 3.0 GHz
VSWR (Voltage standing wave ratio)	1.3 max.
Number of resistors	3 resistors
Number of terminals	4 terminals
Category temperature range	–55 ℃ to +125 ℃

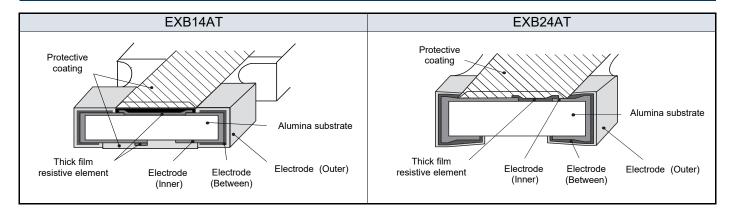
* Please inquire about the other Attenuator value

Power derating curve

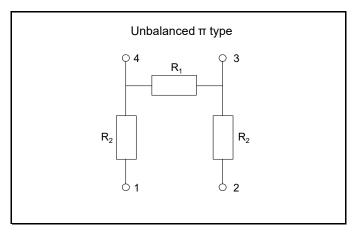
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



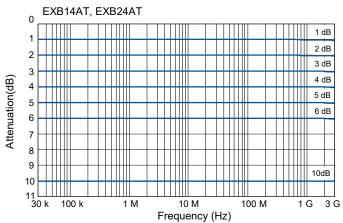
Construction



Circuit configuration

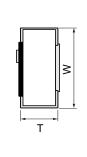


Attenuation-frequency characteristics

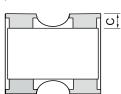


Dimensions (not to scale)



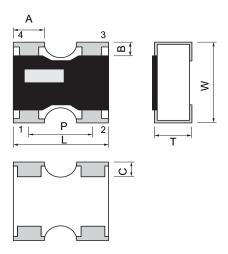


m‡



< Marking Configuration> The bar marking for recognizing terminal direction is located on the side of terminal 3, 4.

EXB24AT



< Marking Configuration> The bar marking for recognizing terminal direction is located on the side of terminal 4.

								Unit : mm	
Part No. Dimensions									
Part NO.	L	W	Т	Α	В	С	P (typical value)	(g/1000 pcs)	
EXB14AT	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	0.15±0.10	0.15±0.10	0.50	0.7	
EXB24AT	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	0.15±0.10	0.25±0.10	0.65	1.1	

Surfac	ce mount resistors series	3			d quantity : pcs/reel)	1
		Size	Pressed	Punched	Punched	Embossed
Products	Part No.	(mm) (inch)	carrier taping	carrier taping	carrier taping	carrier taping
			(2 mm pitch)	(2 mm pitch)	(4 mm pitch)	(4 mm pitch)
	ERJXGN	0402 (01005)	20,000*1	_	_	40,000*2
	ERJ1GN	0603 (0201)	15,000	_	_	_
	ERJ2GE	1005 (0402)	_	10,000	_	_
	ERJ3GE	1608 (0603)	_	_	5,000	_
Thick film	ERJ6GE	2012 (0805)	_	_	5,000	_
chip resistors	ERJ8GE	3216 (1206)	_	_	5,000	_
	ERJ14	3225 (1210)	_	_	_	5,000
	ERJ12	4532 (1812)	_	_	_	5,000
	ERJ12Z	5025 (2010)	_	_	_	5,000
	ERJ1T	6432 (2512)	_	_	_	4,000
	ERJXGN	0402 (01005)	20,000 ^{*1}	_	_	40,000*2
	ERJ1GN/1RH	0603 (0201)	15,000	_	_	_
	ERJ2RC/2RH/2RK	1005 (0402)	_	10,000	_	_
	ERJ3RB/3RE/3EK	1608 (0603)	_	_	5,000	_
Precision	ERJ6RB/6RE/6EN	2012 (0805)	_	_	5,000	_
thick film chip resistors	ERJ8EN	3216 (1206)	_	_	5,000	_
CHIP TESISTOIS	ERJ14N	3225 (1210)	_	_	_	5,000
	ERJ12N	4532 (1812)	_	_	_	5,000
	ERJ12S	5025 (2010)	_	_	_	5,000
	ERJ1TN	6432 (2512)	_	_	_	4,000
	ERA1A	0603 (0201)	15,000	_	_	
Metal film	ERA2A/2V	1005 (0402)		10,000	_	
(Thin film)	ERA3A/3V/3K	1608 (0603)		-	5,000	
chip resistors,	ERA6A/6V/6K	2012 (0805)	_	_	5,000	_
High reliability type	ERA8A	3216 (1206)			5,000	
	ERJ2LW/2BW	1005 (0402)	10,000		— O,000	
	ERJ2BS/2BQ	1005 (0402)		10,000		
	ERJ3L/3B/3R/L03	1608 (0603)			5,000	
	ERJ6L/6B/6C	1000 (0000)			0,000	
This is Char	ERJ6D/6R/L06	2012 (0805)	_	_	5,000	_
Thick film chip resistors/	ERJ8B/8C/8R/L08	3216 (1206)			5,000	
Low resistance type	ERJ14B/14R/L14	3225 (1210)		_	3,000	5,000
	ERJ12R/L12	4532 (1812)	<u>_</u>	_		5,000
	ERJ12Z/L1D	5025 (2010)		_		5,000
	ERJ1TR	6432 (2512)	<u>–</u>	_		4,000
	ERJL1W	6432 (2512)	_	_	_	3,000
	ERJLTW ERJMP2		_	_	_	The second secon
	ERJMP3	3216 (1206)	_	_	_	3,000 3,000
		5025 (2010)	_	_	_	·
Current sensing	ERJMP4	6432 (2512)	_	_	_	2,000
resistors,	ERJMS4	6432 (2512)	_	_	_	2,000
Metal plate type	ERJMS6	6468 (2526)	_	_	_	1,000
	ED IMPA					(8mm Pitch)
	ERJMB1	2550 (1020)	_	_	_	3,000
	ERJM1W	6432 (2512)	_	_	_	3,000
Current sensing resistors, Metal foil type	ERJMFBA	1005 (0402)	_	10,000	_	_
	ERJA1	3264 (1225)	_	_	_	4,000
	ERJB1/ERJC1*3	0207 (1220)				7,000
High power chip resistors/	ERJD1*4	2550 (1020)		_	_	5,000
Wide terminal type	ERJB2/ERJD2*4	1632 (0612)	_	_	5,000	_
	ERJB3	1220 (0508)		_	5,000	

^{*1:} W8P2 : Width 8 mm, Pitch 2 mm,

^{*2:} W4P1 : Width 4 mm, Pitch 1 mm

^{*3:} Anti-Sulfurated High power chip resistors / Wide terminal type

^{*4:} Low TCR High power chip Resistors / Wide terminal type



Surface Mount Resistors Packaging Method (Taping)

0 411.410	e mount resistors series		Pressed	Packaging (Standard	Punched	Embossed
Droduote	Part No.	Size				
Products	Рап №.	(mm) (inch)	carrier taping	carrier taping	carrier taping	carrier taping
	ED IDD3	4000 (0000)	(2 mm pitch)	(2 mm pitch)	(4 mm pitch)	(4 mm pitch)
High precision thick	ERJPB3	1608 (0603)		_	5,000	_
film chip resistors	ERJPB6	2012 (0805)			5,000	
	ERJPA2	1005 (0402)	_	10,000	_	
Anti-Surge Thick film	ERJP03/PA3	1608 (0603)	_	_	5,000	_
chip resistors	ERJP06	2012 (0805)	_	_	5,000	_
·	ERJP08	3216 (1206)	_	_	5,000	_
	ERJP14	3225 (1210)	_	_	_	5,000
Anti-Pulse Thick	ERJT06	2012 (0805)	_	_	5,000	_
film chip resistors	ERJT08	3216 (1206)	_	_	5,000	_
mm omp redictors	ERJT14	3225 (1210)	_		_	5,000
	ERJU0X	0402 (01005)	20,000	_	_	_
	ERJU01	0603 (0201)	15,000	_	_	_
	ERJS02/U02	1005 (0402)	_	10,000	_	
	ERJS03/U03	1608 (0603)	_	_	5,000	_
Anti Culturated	ERJS06/U06					_
Anti-Sulfurated Thick film	ERJU6S/U6Q	2012 (0805)	_	_	5,000	
chip resistors	ERJS08/U08	3216 (1206)	_	_	5,000	_
	ERJS14/U14	3225 (1210)	_	_	_	5,000
	ERJS12/U12	4532 (1812)	_	_	_	5,000
	ERJS1D/U1D	5025 (2010)	_		_	5,000
	ERJS1T/U1T	6432 (2512)	_	_	_	4,000
Anti-Sulfurated	ERJU2R	1005 (0402)	_	10,000	_	_
Thick film chip	ERJU3R	1608 (0603)	_	_	5,000	
resistors /					·	
Precision type	ERJU6R	2012 (0805)		_	5,000	
Anti-Sulfurated	ERJUP3	1608 (0603)	_	_	5,000	_
Thick film chip resistors /	ERJUP6	2012 (0805)	_		5,000	_
Anti-Surge type	ERJUP8	3216 (1206)	_	_	5,000	_
	ERJH2G/2C/2R	1005 (0402)	_	10,000	_	
High temperature thick	ERJH3G/3E/3Q	1608 (0603)			5,000	
film chip resistor	ERJH6G/HP6	2012 (0805)			5,000	
	EXB14V	0806 (0302)		10,000	-	
	EXB24V	1010 (0404)		10,000		
	EXB34V	1616 (0606)	_	10,000	5,000	
				_	· ·	
	EXBV4V	1616 (0606)	_	_	5,000	_
Chip resistor	EXB18V	1406 (0502)		10,000	_	
array	EXB28V	2010 (0804)	_	10,000	_	_
	EXBN8V	2010 (0804)		10,000	_	
	EXB38V	3216 (1206)	_	_	5,000	_
	EXBV8V	3216 (1206)	_	_	5,000	_
	EXBS8V	5022 (2009)	_	_	_	2,500
	EXB2HV	3816 (1506)	_		5,000	
	EXBU14	0806 (0302)	_	10,000	_	_
	EXBU18	1406 (0502)	_	10,000	_	_
	EXBU24	1010 (0404)	_	10,000	_	_
Anti-Sulfurated	EXBU34	1616 (0606)	_	_	5,000	_
chip resistor array	EXBU28	2010 (0804)	_	10,000	_	_
	EXBU38	3216 (1206)	_		5,000	
	EXBU2H	3816 (1506)			5,000	
	EXBD	3216 (1206)	<u> </u>		5,000	
_			_	_	3,000	4 000
hip resistor networks	EXBE	4021 (1608)	_	_	_	4,000
	EXBA	6431 (2512)	_	_	_	4,000
	EXBQ	3816 (1506)	_	_	5,000	-
Chip attenuator	EXB14AT	0806 (0302)	_	10,000	_	
Jinp attoridator	EXB24AT	1010 (0404)		10,000	_	

(2 mm pitch)

øD₁ (Only Emboss)



Carrier tape Embossed carrier Pressed Punched carrier carrier ϕD_0 ≥ 1

Α

Т

Т

Pressed	carrier t	aping (2	2 mm Pi	tch)							
● Chip resisto	Chip resistors / Precision chip / Metal film(Thin film)chip / Low resistance / Anti-Sulfurated								Unit : mm		
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	øD ₀	Т
ERJXGN ERJU0X	0402 (01005)	0.24±0.03	0.45±0.03								0.31±0.05
ERJ1GN ERJ1R□ ERJU01 ERA1A	0603 (0201)	0.38±0.05	0.68±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.42±0.05
ERJ2LW	1005 (0402)	0.68±0.10	1.20±0.10								0.60±0.05
FR.I2RW	, ,	0.67+0.10	1 17+0 10	1	1		1	1	1	l	0 61+0 05

Punched	a carrier i	taping (z mm P	itcn)							
 Chip resistors 	Chip resistors / Precision chip / Thin film chip / Low resistance / Anti-Surge / Anti-Sulfur / High temperature / Metal foil type Unit::								Unit : mm		
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	ϕD_0	T
ERJ2□ ERJPA2 ERJ□□2 ERJ□2□ ERA2□	1005 (0402)	0.67±0.05	1.17±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05
ERJMFBA											0.60±0.05

Chip resistor array / Anti-Sulfurated chip resistor Aarray / Chip attenuator								Unit : mm			
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	ϕD_0	Т
EXB14V	0806	0.70	0.95								
EXB14AT	(0302)	+0.10/-0.05	+0.05/-0.10								
EXB18V	1406 (0502)		1.60±0.10								
EXB24V EXBU24 EXB24AT	1010 (0404)	1.20±0.10	1.20±0.10	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05
EXB28V EXBU28 EXBN8V	2010 (0804)		2.20±0.10								

•	ors / Precision		•	m)cnip / Lo	w resistance	e / Hign pow	ver / Hign pr	ecision / An	ti-Surge /		11-4
Part No.	Anti-Sulfurate Size (inch)	A High ten	nperature B	W	F	E	P ₁	P_2	P ₀	øD ₀	Unit : m
ERJ3 □ ERJ3LW(10mΩ) ERJ3BW ERJ□□3 ERJ□□3 □ ERA3□	1608 (0603)	1.10±0.10	1.90±0.10		·			2	U		0.70±0.05
ERJ3LW(5mΩ)											
ERJ6□ ERJ□□6 ERJ□6□ ERA6□	2012 (0805)	1.65±0.15	2.50±0.20	8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.84±0.05
ERJB3	1220 (0508)									+0.10/0	
ERJ6BW ERJ6LW ERJ6CW	2012 (0805)	1.55±0.15	2.30±0.20								0.94±0.05
ERJ8□ ERJ8□W ERJ□□8 ERA8□	3216 (1206)	2.00±0.15	3.60±0.20								0.84±0.05
ERJB2 ERJD2	1632 (0612)										

•	Chin resistor array	/ / Anti-Sulfurated chin resisto	or array / Chip resistor networks
•	Chip resistor arra	/ / Anti-Sunurated Chip resist	n array / Crip resistor networks

 Chip resist 	or array / Anti-S	Sulfurated cl	hip resistor a	array / Chip	resistor net	works					Unit : mm
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	ϕD_0	Т
EXB34V EXBU34	1616 (0606)		1.95±0.20								
EXB38V EXBU38	3216 (1206)		3.60±0.20								0.70±0.05
EXB2HV EXBU2H	3816 (1506)	1.95±0.15	4.10±0.15	8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	2.00±0.05	4.00±0.10	1.50	
EXBV4V	1616 (0606)		1.95±0.20							+0.10/0	0.84±0.05
EXBV8V	3216 (1206)		3.60±0.20								0.0410.03
EXBD	3216 (1206)	2.00±0.20	3.60±0.20								0.84±0.10
EXBQ	3816 (1506)	1.90±0.20	4.10±0.20								0.64±0.05

Embossed carrier taping (1 mm Pitch)

Chi	o res	ıstors

Only resiste	J1 3										Unit : mm
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P_2	P ₀	ϕD_0	Т
ERJXGN	0402 (01005)	0.25±0.05	0.45±0.05	4.00±0.20	1.80±0.05	0.90±0.10	1.00±0.10	1.00±0.10	2.00±0.10	0.80±0.10	0.5 max.

Embossed carrier taping (4 mm Pitch)

Chip resistors / Precision chip / Low resistance / High power / Anti-Surge / Anti-Pulse / Anti-Sulfurated

Unit: m												Unit : mm
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	ϕD_0	T	øD₁
ERJ14□ ERJ□14	3225 (1210)	2.80±0.20	3.50±0.20	8.00±0.30	3.50±0.05							1.00 +0.10/0
ERJ12□ ERJ□12	4532 (1812)	3.50±0.20	4.80±0.20									
ERJ12Z ERJ12S ERJ⊡1D	5025 (2010)	2.80±0.20	5.30±0.20			1.75	4.00	2.00	4.00	1.50	1.00±0.10	
ERJB1 ERJC1 ERJD1	2550 (1020)	2.0010.20	3.3010.20	12.00 ±0.30	5.50±0.20	±0.10	±0.10	±0.05	±0.10	+0.10/0		15 min.
ERJ1T□ ERJ□1T ERJL1W	6432 (2512)	3.60±0.20	6.90±0.20								1.60±0.10	
ERJA1	3264 (1225)	3.50±0.20	6.80±0.20								1.10±0.20	

Current sensing resistors, Metal plate type

Init	mm
Ollic	

• Carront co.	nomig roototoro,	motal plate	typo									Unit : mm
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P_2	P ₀	ϕD_0	Т	øD₁
ERJMP2 (1 mΩ)	3216 (1206)										1.55±0.20	_
ERJMP2 (2 mΩ)	3216 (1206)	1.90±0.20	3.50±0.20	8.00±0.30	3.50±0.10						1.40±0.20	_
ERJMP2 (3 to 50 mΩ)	3216 (1206)										1.10±0.20	_
ERJMP3 (1 to 2 mΩ)	5025 (2010)			40.00							1.55±0.20	_
ERJMP3 (3 to 50 mΩ)	5025 (2010)	2.90±0.20	5.40±0.20	12.00 ±0.30	5.50±0.10	1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.15±0.20	_
ERJMB1	2550 (1020)										1.55±0.20	_
ERJMP4 (1 to 2 mΩ)	6432 (2512)										1.60±0.20	1.5 min.
ERJMP4 (3 to 50 mΩ)	6432 (2512)	3.50±0.20	6.90±0.20	12.00 ±0.30	5.50±0.10						1.20±0.20	_
ERJMS4	6432 (2512)										1.60±0.20	1.5 min.
ERJM1W	6432 (2512)	1									1.80±0.20	1.5 min.

Chip resistor array / Chip resistor networks

Unit	:	mm	

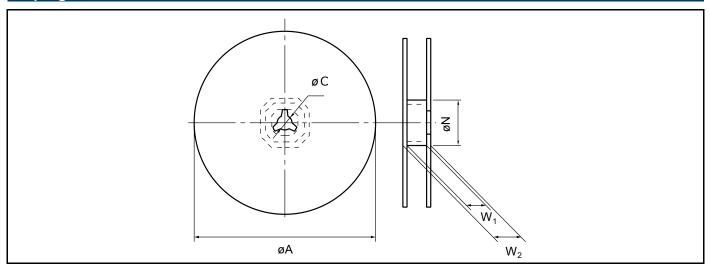
T of the received with a resistant methodic										OTHE : ITHIT		
Part No.	Size (inch)	Α	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	øD₁
EXBS8V	5022 (2009)	2.80±0.20	5.70±0.20				4.00	0.00	4.00	4.50	1.6 max.	
EXBE	4021 (1608)	2.50±0.20	4.40±0.20	12.00±0.30	5.50±0.20	1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.10±0.20	1.5 min.
EXBA	6431 (2512)	3.50±0.20	6.80±0.20				_00	_0.00		0.10/0	1.1010.20	

Embossed carrier taping (8 mm Pitch)

Current ser	● Current sensing resistors, Metal plate type											
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P_0	ϕD_0	Т	øD ₁
ERJMS6	6468 (2526)	6.90±0.20	7.50±0.20	12.00	5.50±0.05	1.75	8.00	2.00	4.00	1.50	2.45±0.20	1.5 min.
EKJIVIOU	0400 (2320)	0.90±0.20	7.50±0.20	±0.30	5.50±0.05	±0.10	±0.10	±0.05	±0.10	+0.10/0	2.43±0.20	1.5 11111.



Taping reel



Unit: mm

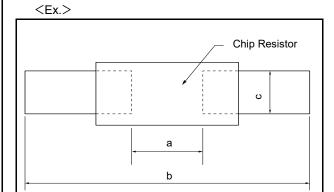
Tape width (W)	Dimensions								
	øA	øN	øС	W ₁	W ₂				
4 mm width	180.0±3.0			4.5±0.5	7.0±0.5				
8 mm width	180.0 0/-1.5	60.0+1.0/0	13.0±0.2	9.0+1.0/0	11.4±1.0				
12 mm width	100.0 0/-1.5		13.0±0.2	13.0+1.0/0	15.4±1.0				
24 mm width	380.0±2.0	80.0±1.0		25.4±1.0	29.4±1.0				

Unit: mm



Recommended land pattern

• An example of a land pattern for the rectangular type is shown below.



High power (double-sided resistive elements structure) type

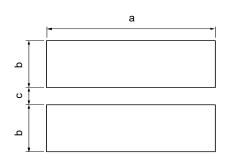
Part No.	Size	Dimensions					
i ait ivo.	(inch)	а	b	С			
ERJ2LW/2BW	1005 (0402)	0.52	1.4 to 1.6	0.4 to 0.6			
ERJ3LW/3BW	1608 (0603)	0.5 to 0.8	2.5 to 2.7	0.9 to 1.1			
ERJ6LW		0.6 to 0.8	3.2 to 3.8	1.1 to 1.4			
ERJ6BW		0.9	3.2 to 3.8	1.1 to 1.4			
ERJ6CW (10 to 13 mΩ)	2012 (0805)	0.7 to 0.9	3.2 to 3.8	1.1 to 1.4			
ERJ6CW (15 to 30 mΩ)		0.9 to 1.1	3.2 to 3.8	1.1 to 1.4			
ERJ8BW							
ERJ8CW (10 to 16 mΩ)	3216 (1206)	1.2	4.4 to 5.0	1.3 to 1.8			
ERJ8CW (18 to 50 mΩ)		2.0 to 2.6	4.4 to 5.0	1.2 to 1.8			

Unit : mm

Size	Dimensions							
mm/inch	а	b	С					
0402/01005	0.15 to 0.20	0.5 to 0.7	0.20 to 0.25					
0603/0201	0.3 to 0.4	0.8 to 0.9	0.25 to 0.35					
1005/0402	0.5 to 0.6	1.4 to 1.6	0.4 to 0.6					
1608/0603	0.7 to 0.9	2.0 to 2.2	0.8 to 1.0					
2012/0805	1.0 to 1.4	3.2 to 3.8	0.9 to 1.4					
3216/1206	2.0 to 2.4	4.4 to 5.0	1.2 to 1.8					
3225/1210	2.0 to 2.4	4.4 to 5.0	1.8 to 2.8					
4532/1812	3.3 to 3.7	5.7 to 6.5	2.3 to 3.5					
5025/2010	3.6 to 4.0	6.2 to 7.0	1.8 to 2.8					
6432/2512	5.0 to 5.4	7.6 to 8.6	2.3 to 3.5					
6432/2512*	3.6 to 4.0	7.6 to 8.6	2.3 to 3.5					

^{*} ERJL1W

• An example of a land pattern for high power chip resistors / Wide terminal type is shown below.



			Unit : mm					
Part No.	Dimensions							
Fait NO.	а	b	С					
ERJA1	6.4	1.70	0.60					
ERJB1								
ERJC1*1	5.0	1.30	0.75					
ERJD1*2								
ERJB2	3.2	0.95	0.70					
ERJD2*2	3.2	0.95	0.70					
ERJB3	2.0	0.80	0.60					

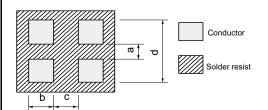
^{*1:} Anti-Sulfurated High power chip resistors / Wide terminal type

^{*2:} Low TCR High power chip resistors / Wide terminal type



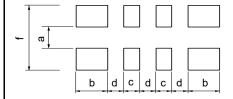
Recommended land pattern

• An example of a land pattern for Chip Resistor Array, Anti-Sulfurated Chip Resistor Array and Chip Attenuator is shown below.



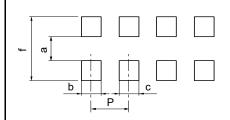
Part No.	Dimensions							
Fait No.	а	b	С	d				
EXB14V EXB14A	0.30	0.30	0.30	0.80 to 0.90				
EXB24V EXBU24 EXB24A	0.5	0.35 to 0.40	0.30	1.4 to 1.5				

Unit : mm

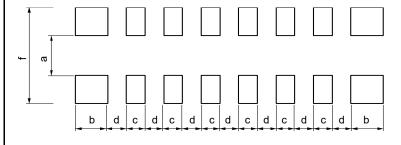


Part No.	Dimensions				
i ait ivo.	а	b	С	d	f
EXB28V EXBU28	0.40	0.525	0.25	0.25	1.40
EXBN8V	0.45 to 0.50	0.35 to 0.38	0.25	0.25	1.40 to 2.00

Unit: mm



David Nia	Dimensions					
Part No.	а	b	С	f	Р	
EXB18V	0.20 to 0.30	0.15 to 0.20	0.15 to 0.20	0.80 to 0.90	0.40	
EXBV4V EXBV8V	0.7 to 0.9	0.4 to 0.45	0.4 to 0.45	2 to 2.4	0.80	
EXB34V EXB38V EXBU34 EXBU38	0.7 to 0.9	0.4 to 0.5	0.4 to 0.5	2.2 to 2.6	0.80	
EXBS8V	1 to 1.2	0.5 to 0.75	0.5 to 0.75	3.2 to 3.8	1.27	



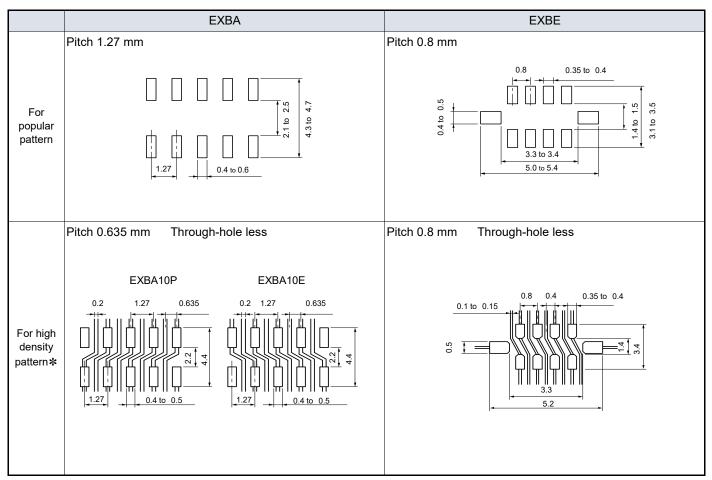
Unit:mm

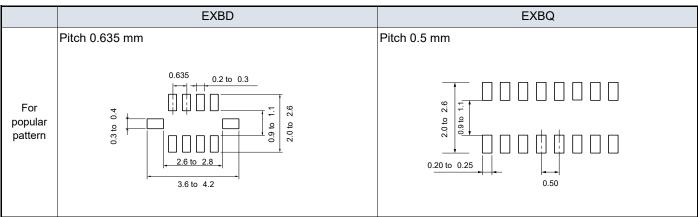
Part No.	Dimensions				
Fall NO.	а	b	С	d	f
EXB2HV EXBU2H	1.00	0.425	0.25	0.25	2.00



Recommended land pattern

• An example of a land pattern for Chip Resistor Networks is shown below.





* When designing high density land patterns, examine the reliability of isolation among the lines and adopt the chip resistor networks.

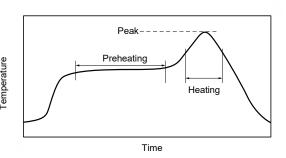


Recommended soldering conditions (Rectagular type)

Recommendations and precautions are described below.

• Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- •Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



For soldering (Example : Sn/Pb)

· · · · · · · · · · · · · · · · · · ·	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

For lead-free soldering (Example: Sn/Ag/Cu)

Tel lead nee seldering (Example : en,, ig, ea)				
	Temperature	Time		
Preheating	150 ℃ to 180 ℃	60 s to 120 s		
Main heating	Above 230 ℃	30 s to 40 s		
Peak	max. 260 ℃	max. 10 s		

• Recommended soldering conditions for flow

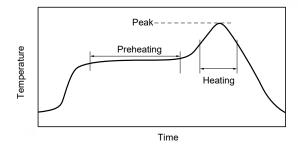
	For soldering		For lead-free soldering	
	Temperature	Time	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s	150 ℃ to 180 ℃	60 s to 120 s
Soldering	245 ± 5 ℃	20 s to 30 s	max. 260 ℃	max. 10 s

Recommended soldering conditions (Chip resistor array / networks and Chip attenuator)

Recommendations and precautions are described below.

Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



For soldering (Example : Sn/Pb)

	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

For lead-free soldering (Example : Sn/Ag/Cu)

	<u> </u>	0 /
	Temperature	Time
Preheating	150 ℃ to 180 ℃	60 s to 120 s
Main heating	Above 230 ℃	30 s to 40 s
Peak	max. 260 ℃	max. 10 s

Flow soldering

We do not recommend flow soldering, because a solder bridge may form. Please contact us regarding flow sol der ing of EXBA series.



Standard for resistance value and resistance tolerance

Basis standard

IEC Publication 60062 : Marking codes for resistors and capacitors.

IEC Publication 60063 : Preferred number series forresistors and capacitors.

JIS C 5062 : Marking codes for resistors and capacitors.

JIS C 5063 : Preferred number series for resistors and capacitors.

Resistance values

The resistance values are notched by "Ratio" below in each series.

Series	Resistance tolerance (Standard)	Ratio	Remarks
E6	±20 %	6√10=1.46	
E12	±10 %	¹²√10=1.21	
E24	± 5 %	²⁴ √10=1.10	Please refer to standard resistance values shown on this catalog.
E48	± 2 %	48√10=1.05	,
E96	± 1%	⁹⁶ √10=1.02	

How to express the resistance value with a Panasonic part number

The resistance value expressed in ohms is iden tified by a three digit number or a four digit number.

The last digit specifies the number of zeroes to follow.

The letter "R" shall be used as the decimal point for less than 10 Ω .

The examples of a three digit number

Resistance code	Value in ohms (Ω)
R56	0.56
5R6	5.6
100	10
271	270
102	1 k
273	27 k
104	100 k
275	2.7 M
106	10 M
107	100 M

The examples of a four digit number

Resistance code	Value in ohms (Ω)
R562	0.562
5R62	5.62
56R2	56.2
1000	100
2711	2.71 k
1002	10 k
2713	271 k
1004	1 M
2751	2.71 M
1006	100 M

How to express the resistance tolerance with a Panasonic part number

The resistance tolerance is identified by a single letter in accordance with the following table and the code is placed just before the resistance code in the following examples.

Tolerance code	Tolerance (%)	Examples
W	± 0.05	W1001 : 1000 Ω ± 0.05 %
В	± 0.1	B1001 : 1000 Ω ± 0.1 %
С	± 0.25	C1001 : 1000 Ω ± 0.25 %
D	± 0.5	D1001 : 1000 Ω ± 0.5 %
F	± 1	F1001 : 1000 Ω ± 1 %
G	± 2	G1001 : 1000 Ω ± 2 %
J	± 5	J101 : 100 Ω ± 5 %
K	± 10	K101 : 100 Ω ± 10 %
М	± 20	M101 : 100 Ω ± 20 %



Standard resistance values

0.00	uaru		arice	values
E6	E12	E24	E48	E96
	10	10	100	100
				102
			105	105
				107
		11	110	110
				113
			115	115
				118
10		12	121	121
				124
			127	127
				130
	12	13	133	133
				137
			140	140
			140	143
			147	147
	15	15		150
			154	154
		16		158
			162	162
				165
			169	169
				174
15	18		178	178
		18		182
			187	187
				191
			196	196
		20		200
			205	205
				210

E6	E12	E24	E48	E96
	22	22	215	215
				221
			226	226
				232
			237	237
		24		243
			249	249
				255
22			261	261
				267
			074	274
		27	274	280
			007	287
	27		287	294
			301	301
		30	301	309
			316	316
				324
	33	33	332	332
				340
			348	348
				357
		36	365	365
				374
33			383	383
	39	39		392
			402	402
				412
			422	422
		43		432
			442	442
				453

E6	E12	E24	E48	E96
	47	47	464	464
				475
			487	487
				499
		51	511	511
				523
			536	536
47				549
47		50	562	562
				576
		56	50 -5	590
	56		590	604
	30		619	619
		62	019	634
		02	649	649
			049	665
	68	68	681	681
				698
			715	715
				732
		75	750	750
				768
			787	787
68				806
00	82	82	825	825
				845
			866	866
				887
		91	909	909
				931
				953
				976

Safty Precautions

When using our products, no matter what sort of equipment they might be used for, be sure to confirm the applications and environmental conditions with our specifications in advance.



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